1. OUTLINE

1.1 Features

Ultra-low power consumption technology

- V_{DD}= 2.4 to 5.5 V
- HALT mode
- STOP mode
- SNOOZE mode

RL78 CPU core

- CISC architecture with 3-stage pipeline
- Minimum instruction execution time: Can be changed from high speed (0.03125 µs: @ 32 MHz operation with high-speed on-chip oscillator or PLL clock)Note to ultra-low speed (1 µs: @ 1 MHz operation with high-speed on-chip oscillator or PLL clock)
- Multiply/divide/multiply & accumulate instructions are supported.
- Address space: 1 MB
- General-purpose registers: (8-bit register × 8) × 4 banks
- On-chip RAM: 8 KB

Note For industrial applications (M; T_A = –40 to +125°C): 0.04167 µs @ 24 MHz operation with high-speed on-chip oscillator or PLL clock

Code flash memory

- Code flash memory: 32 KB
- Block size: 1 KB
- Prohibition of block erase and rewriting (security function)
- On-chip debug function
- Self-programming (with boot swap function/flash shield window function)

Data flash memory

- Data flash memory: 4 KB
- Back ground operation (BGO): Instructions can be executed from the program memory while rewriting the data flash memory.
- Number of rewrites: 1,000,000 times (TYP.)
- Voltage of rewrites: V_{DD} = 2.4 to 5.5 V

High-speed on-chip oscillator

- Select from 32 MHz, 24 MHz, 16 MHz, 12 MHz, 8 MHz, 6 MHz, 4 MHz, 3 MHz, 2 MHz, and 1 MHz
- High accuracy:
  ±2.0% (V_{DD} = 2.4 to 5.5 V, T_A = –40 to +105°C)
  ±3.0% (V_{DD} = 2.4 to 5.5 V, T_A = –40 to +125°C)

Operating ambient temperature

- T_A = –40 to +105°C (G: Industrial applications)
- T_A = –40 to +125°C (M: Industrial applications)

Power management and reset function

- On-chip power-on-reset (POR) circuit
- On-chip voltage detector (LVD) (Select interrupt and reset from 7 levels)

Data transfer controller (DTC)

- Transfer modes: Normal transfer mode, repeat transfer mode, block transfer mode
- Activation sources: Activated by interrupt sources.
- Chain transfer function

Event link controller (ELC)

- Event signals of 16 types can be linked to the specified peripheral function.

Serial interfaces

- Simplified SPI(CSI): 2 channels
- UART: 2 channels (UART with LIN-bus supported: 1 channel)
- I^2C/simplified I^2C: 2 channels

Timer

- 16-bit timer: 8 channels
  (Timer Array Unit (TAU): 6 channels, timer RJ: 1 channel, timer RG: 1 channel)
- Interval timer: 1 channel
- Real-time clock: 1 channel (calendar for 99 years, alarm function, and clock correction function)
- Watchdog timer: 1 channel (operable with the dedicated low-speed on-chip oscillator)

Analog front-end (AFE) power supply

- Sensor power supply (SBIAS) output: 0.5 V to 2.2 V

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24-bit ΔΣ A/D converter with programmable gain instrumentation amplifier

- 24-bit second-order ΔΣ A/D converter (AV_{DD} = 2.7 to 5.5 V)
- SNDR: 85 dB (TYP.)
- Output data rate:
  488 sps to 15.625 ksps in normal mode
  61 sps to 1.953 ksps in low power mode
- Programmable gain instrumentation amplifier input: 3 or 4 channels
  (differential input mode or single-ended input mode can be specified for each input channel)
- DAC for offset adjustment
- Variable gain: x1 to x64
- On-chip temperature sensor

10-bit A/D converter

- 8-bit/10-bit successive approximation A/D converter (AV_{DD} = 2.7 to 5.5 V)
- Analog input: 8 or 10 channels, sensor power supply (SBIAS), and internal reference voltage
- Internal reference voltage (1.45 V)

Configurable amplifier

- Matrix configuration that consists of 3 operational amplifier channels and a configurable switch (AV_{DD} = 2.7 to 5.5 V)
- Can be used as a 2- or 3-channel general operational amplifier
- Operational amplifier output: 3 channels
- General-purpose Analog I/O ports: 5 or 6 channels
- Offset voltage calibration

D/A converter

- 12-bit R-2R resistor ladder type D/A converter (AV_{DD} = 2.7 to 5.5 V)
- Analog output: 1 channel (via configurable amplifier)

I/O port

- CMOS I/O: 10 to 14 (N-ch open drain I/O [withstanding voltage of V_{DD}]: 6, CMOS I/O: 7 to 11, CMOS input: 3)
- Can be set to TTL input buffer and on-chip pull-up resistor
- Different potential interface: Can connect to a 2.5/3 V device
- On-chip clock output/buzzer output controller

Others

- On-chip BCD (binary-coded decimal) correction circuit

Note Although the CSI function is generally called SPI, it is also called CSI in this product, so it is referred to as such in this manual.

○ ROM, RAM capacities

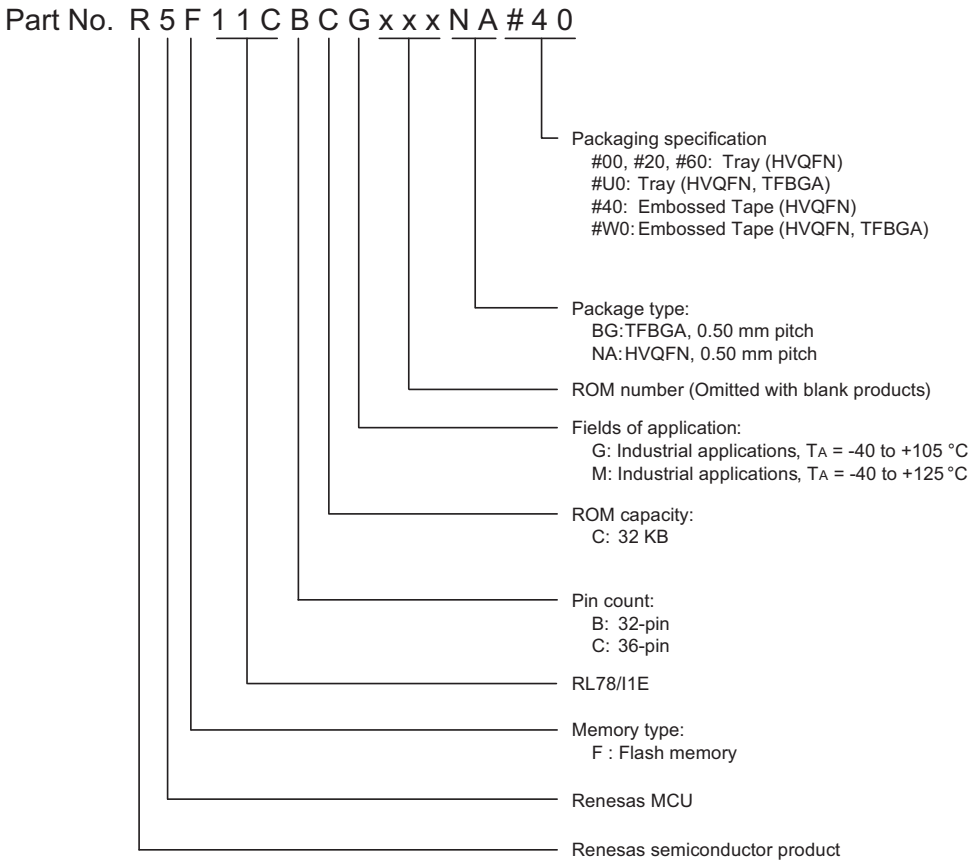
Flash ROM	Data flash	RAM	RL78/I1E	
			32 pins	36 pins
32 KB	4 KB	8 KB	R5F11CBC	R5F11CCC

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1.2 Ordering Information

<R>

Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E



<R>

Pin count	Package	Fields of Application Note	Ordering Part Number
32 pins	32-pin plastic HVQFN (5 × 5 mm, 0.5 mm pitch)	G	R5F11CBCGNA#20 R5F11CBCGNA#40 R5F11CBCGNA#00 R5F11CBCGNA#60
		M	R5F11CBCMNA#U0 R5F11CBCMNA#W0
36 pins	36-pin plastic TFBGA (4 × 4 mm, 0.5 mm pitch)	G	R5F11CCCGBG#U0 R5F11CCCGBG#W0
		M	R5F11CCCMBG#U0 R5F11CCCMBG#W0

Note For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E**.

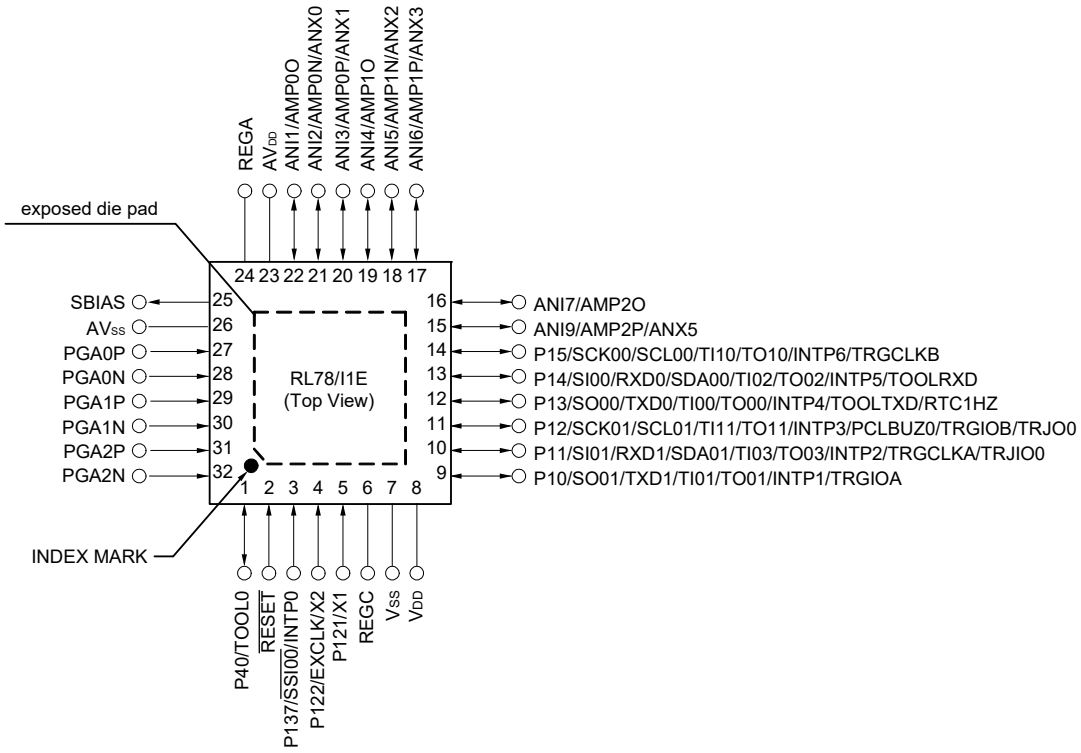
Caution **The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.**

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1.3 Pin Configuration (Top View)

1.3.1 32-pin products

• 32-pin plastic HVQFN (5 × 5 mm, 0.5 mm pitch)



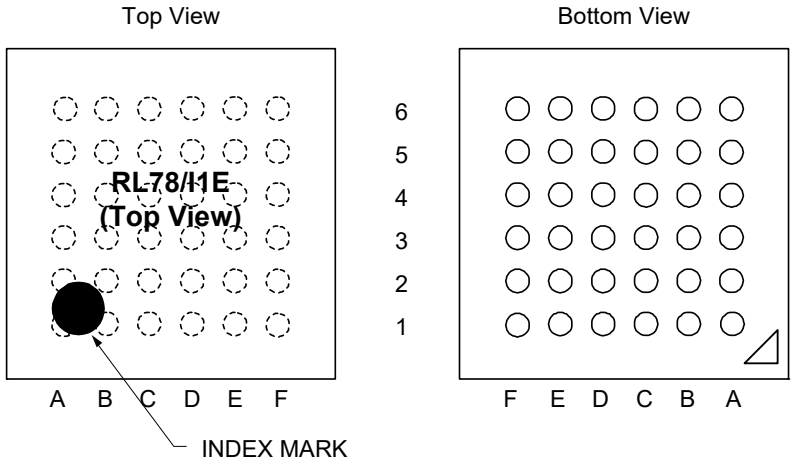
Caution 1. Connect the REGC pin to the Vss pin via a capacitor (0.47 to 1 μF).
Caution 2. Connect the REGA pin to the AVss pin via a capacitor (0.22 μF).
Caution 3. Make the AVss pin the same potential as the Vss pin.
Caution 4. Make the AVDD pin the same potential as the VDD pin.
Caution 5. Connect the SBIAS pin to the AVss pin via a capacitor (0.22 μF).

Remark 1. It is recommended to connect an exposed die pad to Vss.

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1.3.2 36-pin products

• 36-pin plastic TFBGA (4 × 4 mm, 0.5 mm pitch)



	A	B	C	D	E	F	
6	PGA2P	PGA1N	PGA1P	PGA0P	PGA3P	AVSS	6
5	PGA2N	P40/TOOL0	PGA0N	PGA3N	REGA	SBIAS	5
4	RESET	P137/SSI00/ INTP0	P11/SI01/RXD1/ SDA01/TI03/ TO03/INTP2/ TRGCLKA/ TRJIO0	P12/SCK01/ SCL01/TI11/ TO11/INTP3/ PCLBUZ0/ TRGIOB/TRJO0	ANI0	AVDD	4
3	P122/EXCLK/X2	P15/SCK00/ SCL00/TI10/ TO10/INTP6/ TRGCLKB	P10/SO01/TXD1/ TI01/TO01/ INTP1/TRGIOA	ANI3/AMP0P/ ANX1	ANI2/AMP0N/ ANX0	ANI1/AMP0O	3
2	P121/X1	REGC	P14/SI00/RXD0/ SDA00/TI02/ TO02/INTP5/ TOOLRXD	P41/ANI6/ AMP1P/ANX3	P42/ANI5/ AMP1N/ANX2	ANI4/AMP1O	2
1	VDD	VSS	P13/SO00/TXD0/ TI00/TO00/INTP4/ TOOLTXD/ RTC1HZ	P16/INTP7/ANI9/ AMP2P/ANX5	P17/ANI8/ AMP2N/ANX4	ANI7/AMP2O	1
	A	B	C	D	E	F	

Caution 1. Connect the REGC pin to the VSS pin via a capacitor (0.47 to 1 μF).
Caution 2. Connect the REGA pin to the AVSS pin via a capacitor (0.22 μF).
Caution 3. Make the AVSS pin the same potential as the VSS pin.
Caution 4. Make the AVDD pin the same potential as the VDD pin.
Caution 5. Connect the SBIAS pin to the AVSS pin via a capacitor (0.22 μF).

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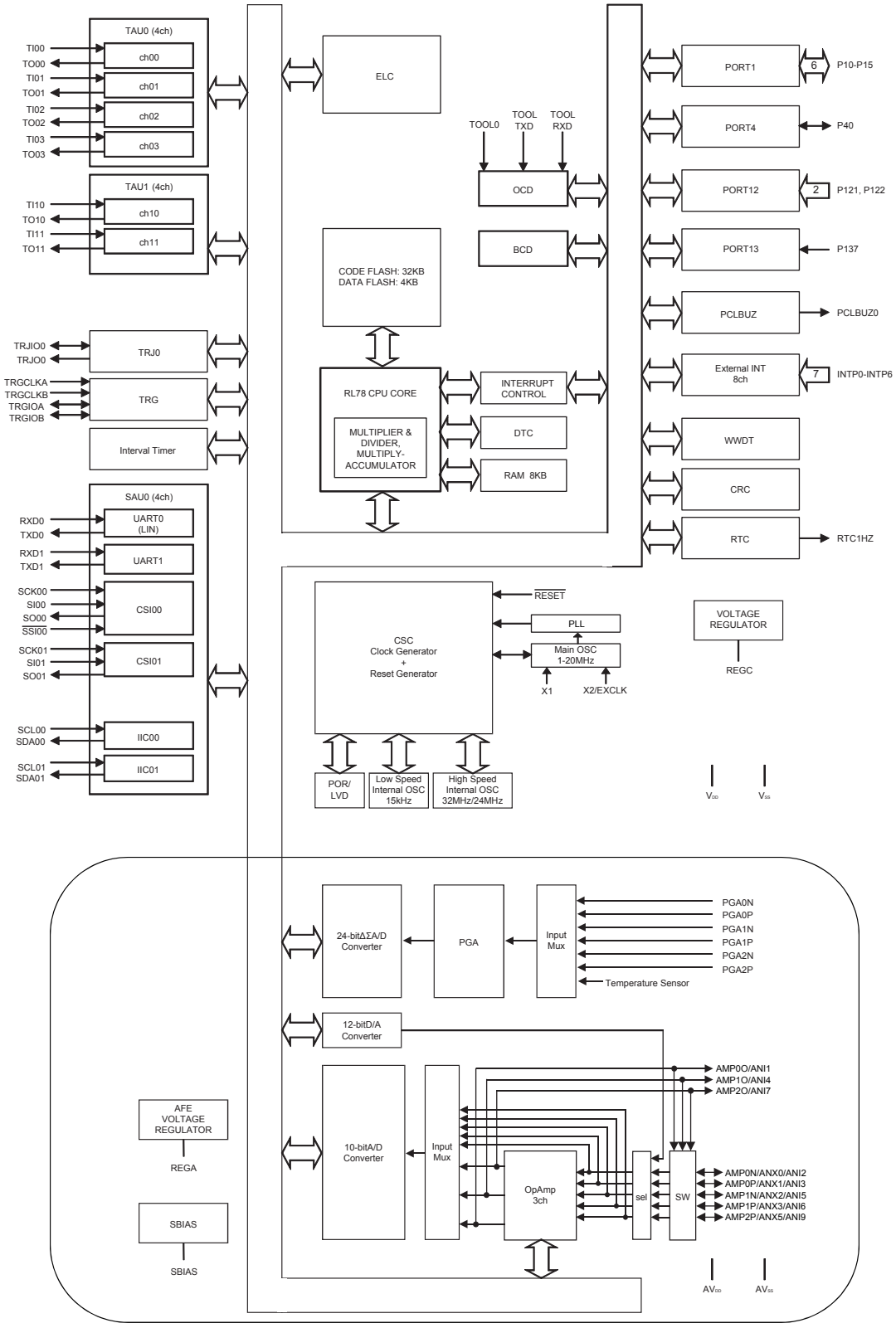
1.4 Pin Identification

ANI0 to ANI9:	Analog input	$\overline{\text{RESET}}$:	Reset
AMP0P to AMP2P:	Operational amplifier positive input	REGA:	Regulator capacitance for analog
		REGC:	Regulator capacitance
AMP0N to AMP2N:	Operational amplifier negative input	RTC1HZ:	Real-time clock correction
		RxD0, RxD1:	Receive data
AMP0O to AMP2O:	Operational amplifier output	SBIAS:	Bias output for MEMS sensor
ANX0 to ANX5:	General-purpose analog ports for operational amplifier	SCK00, SCK01:	Serial clock input/output
		SCL00, SCL01:	Serial clock output
AV_{DD}:	Power supply for analog	SI00, SI01:	Serial data input
AV_{SS}:	Ground for analog	SO00, SO01:	Serial data output
EXCLK:	External clock input (main system clock)	TI00 to TI03, TI10, TI11:	Timer input
		TO00 to TO03, TO10, TO11, TRJO0:	Timer output
INTP0 to INTP7:	External interrupt input		
P10 to P17:	Port 1	TOOL0:	Data input/output for tools
P40 to P42:	Port 4	TOOLRxD, TOOLTxD:	Data input/output for external devices
P121, P122:	Port 12	TRGCLKA, TRGCLKB:	Timer external clock input
P137:	Port 13	TRGIOA, TRGIOB, TRJIO0:	Timer input/output
PCLBUZ0:	Programmable clock output/ buzzer output	TxD0, TxD1:	Transmit data
		V_{DD}:	Power supply
PGA0N to PGA3N:	PGA negative analog input	V_{SS}:	Ground
PGA0P to PGA3P:	PGA positive analog input	X1, X2:	Crystal oscillator (main system clock)

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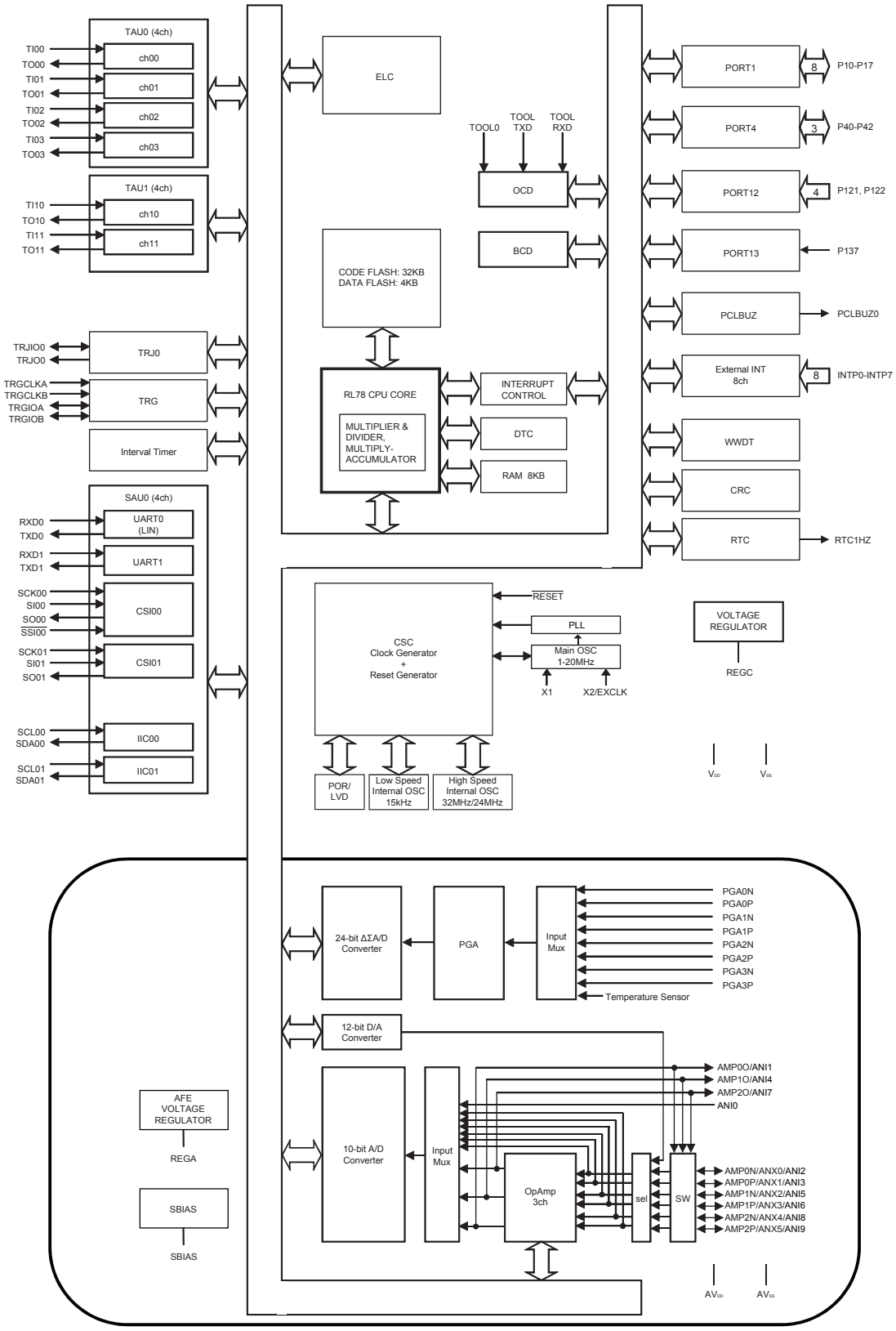
1.5 Block Diagram

1.5.1 32-pin products



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1.5.2 36-pin products



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1.6 Outline of Functions

[32-pin, 36-pin products]

(1/2)

Item		32-pin	36-pin
		R5F11CBC	R5F11CCC
Code flash memory		32 KB	
Data flash memory		4 KB	
RAM		8 KB	
Address space		1 MB	
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) 1 to 20 MHz: V_{DD} = 2.7 to 5.5 V, 1 to 16 MHz: V_{DD} = 2.4 to 2.7 V	
	High-speed on-chip oscillator clock (f_{IH})	1 to 32 MHz (V_{DD} = 2.7 to 5.5 V)Note 1 1 to 16 MHz (V_{DD} = 2.4 to 5.5 V)	
	PLL clock (f_{PLL} divided by 2, 4, or 8)	3 to 32 MHz (V_{DD} = 2.7 to 5.5 V)Note 2 3 to 16 MHz (V_{DD} = 2.4 to 5.5 V)	
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)	
Minimum instruction execution time		0.03125 µs (high-speed on-chip oscillator clock: f_{IH} = 32 MHz operation)Note 3	
		0.03125 µs (PLL clock: f_{PLL} = 64 MHz, f_{IH} = 32 MHz operation)Note 4	
		0.05 µs (high-speed system clock: f_{MX} = 20 MHz operation)	
Instruction set		• Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits × 8 bits, 16 bits × 16 bits), division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits) • Multiplication and Accumulation (16 bits × 16 bits + 32 bits) • Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.	
I/O port	Total	10	14
	CMOS I/O	7	11
	CMOS input	3	3
Timer	16-bit timer	8 channels (TAU: 6 channels, Timer RJ: 1 channel, Timer RG: 1 channel)	
	Watchdog timer	1 channel	
	Real-time clock (RTC)	1 channel	
	Interval timer	1 channel	
	Timer output	Timer outputs: 10 channels PWM outputs: 9 channels	
	RTC output	1	
Clock output/buzzer output		1	
		2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f_{MAIN} = 20 MHz operation)	
8/10-bit A/D converter		8 channels	10 channels
Serial interface		Simplified SPI(CSI): 2 channels/UART: 2 channels (UART supporting LIN-bus: 1 channel)/simplified I^2C: 2 channels	

Note 1. 1 to 24 MHz (V_{DD} = 2.7 to 5.5 V) for M products (industrial applications, T_A = –40 to +125°C)

Note 2. 3 to 24 MHz (V_{DD} = 2.7 to 5.5 V) for M products (industrial applications, T_A = –40 to +125°C)

Note 3. 0.04167 µs (high-speed on-chip oscillator clock: f_{IH} = 24 MHz operation) for M products (industrial applications, T_A = –40 to +125°C)

Note 4. 0.04167 µs (PLL clock: f_{PLL} = 64 MHz, f_{IH} = 24 MHz operation) for M products (industrial applications, T_A = –40 to +125°C

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(2/2)

Item		32-pin	36-pin
		R5F11CBC	R5F11CCC
Data transfer controller (DTC)		22 sources	
Event link controller (ELC)		Event input: 16 Event trigger output: 7	
Vectored interrupt sources	Internal	23	23
	External	7	8
ΔΣ A/D converter	24-bit	3 channels	4 channels
	AFE temperature sensor	1 channel	
Operational amplifier	3-pin	3 channels Note 1	3 channels
	General-purpose port	5 channels	6 channels
D/A converter	12-bit	1 channel	
Reset		• Reset by $\overline{\text{RESET}}$ pin • Internal reset by watchdog timer • Internal reset by power-on-reset • Internal reset by voltage detector • Internal reset by illegal instruction execution Note 2 • Internal reset by RAM parity error • Internal reset by illegal-memory access	
Power-on-reset circuit		• Power-on-reset: 1.56 ±0.03 V • Power-down-reset: 1.55 ±0.03 V	
Voltage detector		• At rise: 2.55 V to 4.64 V (7 steps) • At fall: 2.61 V to 4.74 V (7 steps)	
On-chip debug function		Provided	
Power supply voltage		V_{DD} = 2.4 to 5.5 V	
Operating ambient temperature		T_A = –40 to +105°C (G: Industrial applications), T_A = –40 to +125°C (M: Industrial applications)	

Note 1. When each of the 3 channels is in use as an independent amplifier, at least one channel must be in a voltage follower configuration.

Note 2. The illegal instruction is generated when instruction code FFH is executed.
Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

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2. ELECTRICAL SPECIFICATIONS (G: T_A = -40 to +105°C)

This chapter describes the electrical specifications for the products “G: Industrial applications (T_A = -40 to +105°C)”.

Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

Caution 2. The pins mounted depend on the product.

Caution 3. Please contact Renesas Electronics sales office for derating of operation under T_A = +85 to +105°C. Derating is the systematic reduction of load for the sake of improved reliability.

Remark The electrical characteristics of the products G: Industrial applications (T_A = -40 to +105°C) are different from those of the products “M: Industrial applications”. For details, refer to **2.1** to **2.10**.

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2.1 Absolute Maximum Ratings

Absolute Maximum Ratings **(1/2)**

Parameter	Symbol	Conditions		Ratings	Unit
Supply voltage	V_{DD}			-0.5 to +6.5	V
	AV_{DD}	AV_{DD} = V_{DD}		-0.5 to +6.5	V
	AV_{SS}	AV_{SS} = V_{SS}		-0.5 to +0.3	V
REGC pin input voltage	V_{IREGC}	REGC		-0.3 to +2.8 and -0.3 to V_{DD} + 0.3 Note 1	V
REGA pin input voltage	V_{IREGA}	REGA		-0.3 to +2.8 and -0.3 to AV_{DD} + 0.3 Note 2	V
Input voltage	V_{I1}	P10 to P15, P40, P121, P122, P137, EXCLK, $\overline{\text{RESET}}$		-0.3 to V_{DD} +0.3 Note 3	V
Alternate-function pin input voltage	V_{I2}	P16, P17, P41, P42 (36-pin products only)	Digital input voltage	-0.3 to V_{DD} + 0.3 Note 3	V
			Analog input voltage	-0.3 to AV_{DD} + 0.3 Note 3	V
Analog input voltage	V_{IA}	PGA0P to PGA3P, PGA0N to PGA3N, ANI0 to ANI9, ANX0 to ANX5		-0.3 to AV_{DD} + 0.3 Note 3	V
Output voltage	V_{O1}	P10 to P15, P40		-0.3 to V_{DD} + 0.3 Note 3	V
Alternate-function pin output voltage	V_{O2}	P16, P17, P41, P42 (36-pin products only)	Digital output voltage	-0.3 to V_{DD} + 0.3 Note 3	V
			Analog output voltage	-0.3 to AV_{DD} + 0.3 Note 3	V
Analog output voltage	V_{OA}	SBIAS, AMP0O to AMP2O, ANX0 to ANX5		-0.3 to AV_{DD} + 0.3 Note 3	V

Note 1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

Note 2. Connect the REGA pin to AV_{SS} via a capacitor (0.22 μF). This value regulates the absolute maximum rating of the REGA pin. Do not use this pin with voltage applied to it.

Note 3. Must be 6.5 V or lower.

Caution **Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.**

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{SS} is used as the reference voltage.

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Absolute Maximum Ratings **(2/2)**

Parameter	Symbol	Conditions		Ratings	Unit
Output current, high	I_{OH1}	Per pin	P10 to P17, P40 to P42	-40	mA
		Total of all pins	P10 to P17, P41, P42 Note	-100	mA
Analog output current, high	I_{OHA}	Per pin	AMP0O to AMP2O	-12	mA
			ANX0 to ANX5	-0.12	mA
		Total of all pins	AMP0O to AMP2O, ANX0 to ANX5	-18	mA
Output current, low	I_{OL1}	Per pin	P10 to P17, P40 to P42	40	mA
		Total of all pins	P10 to P17, P41, P42 Note	100	mA
Analog output current, low	I_{OLA}	Per pin	AMP0O to AMP2O	12	mA
			ANX0 to ANX5	0.12	mA
		Total of all pins	AMP0O to AMP2O, ANX0 to ANX5	18	mA
Operating ambient temperature	T_A	In normal operation mode		-40 to +105	°C
		In flash memory programming mode			
Storage temperature	T_{stg}			-65 to +150	°C

Note This indicates the total current value when P16, P17, P41, and P42 are used as digital input pins.

Caution **Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.**

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
Remark 2. V_{SS} is used as the reference voltage.

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2.2 Oscillator Characteristics

2.2.1 X1 characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (f_X) Note	Ceramic resonator/ crystal resonator	2.7 V ≤ V_{DD} ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ V_{DD} < 2.7 V	1.0		16.0	

Note Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

2.2.2 On-chip oscillator characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency Notes 1, 2	f_{IH}	2.7 V ≤ V_{DD} ≤ 5.5 V		1		32	MHz
		2.4 V ≤ V_{DD} < 2.7 V		1		16	MHz
High-speed on-chip oscillator clock frequency accuracy		-40 to +105°C	2.4 V ≤ V_{DD} ≤ 5.5 V	-2.0		+2.0	%
Low-speed on-chip oscillator clock frequency	f_{IL}				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

Note 1. High-speed on-chip oscillator frequency is selected with bits 0 to 3 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

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2.2.3 PLL characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
PLL output frequency Notes 1, 2, 3	f_{PLL}	f_{MX} = 8 MHz	DSFRDIV = 0	DSCM = 0		48		MHz
				DSCM = 1		64		MHz
			DSFRDIV = 1	DSCM = 0		24		MHz
				DSCM = 1		32		MHz
		f_{MX} = 4 MHz	DSFRDIV = 0	DSCM = 0		24		MHz
				DSCM = 1		32		MHz
Lockup wait time		Time from when PLL output is enabled to when the phase is locked			40			µs
Interval wait time		Time from when the PLL stops operating to when the setting to start PLL operation is specified			4			µs
Setup wait time		Time required from when the PLL input clock stabilizes and the PLL setting is determined to when the PLL is activated			1			µs

Note 1. When using a PLL, input a clock of 4 MHz or 8 MHz to the PLL.

Note 2. Be sure to specify one of these settings when using a PLL.

Note 3. When using the PLL output as the CPU clock, f_{IH} is divided by 2, 4, or 8 according to the setting of the RDIV1 and RDIV0 bits.

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2.3 DC Characteristics

2.3.1 Pin characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/3)**

Item	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high Note 1	I_{OH1}	Per pin for P10 to P17 and P40 to P42 Note 2	-40°C < T_A ≤ +85°C			-10.0 Note 3	mA
			85°C < T_A ≤ 105°C			-3.0 Note 3	mA
		Total of P10 to P17, P41, and P42 Note 2 (When duty ≤ 70% Note 4)	4.0 V ≤ V_{DD} ≤ 5.5 V -40°C < T_A ≤ +85°C			-80.0	mA
			4.0 V ≤ V_{DD} ≤ 5.5 V 85°C < T_A ≤ 105°C			-30.0	mA
			2.7 V ≤ V_{DD} < 4.0 V			-19.0	mA
			2.4 V ≤ V_{DD} < 2.7 V			-10.0	mA
Output current, low Note 1	I_{OL1}	Per pin for P10 to P17 and P40 to P42 Note 2	-40°C < T_A ≤ +85°C			20.0 Note 3	mA
			85°C < T_A ≤ 105°C			8.5 Note 3	mA
		Total of P10 to P17, P41, and P42 Note 2 (When duty ≤ 70% Note 4)	4.0 V ≤ V_{DD} ≤ 5.5 V -40°C < T_A ≤ +85°C			80.0	mA
			4.0 V ≤ V_{DD} ≤ 5.5 V 85°C < T_A ≤ 105°C			40.0	mA
			2.7 V ≤ V_{DD} < 4.0 V			35.0	mA
			2.4 V ≤ V_{DD} < 2.7 V			20.0	mA

Note 1. Value of current at which the device operation is guaranteed even if the current flows from the V_{DD} pin to an output pin.

Note 2. This indicates the total current value when P16, P17, P41, and P42 are used as digital I/O ports. When using these pins as analog function (AFE) pins, refer to **2.1 Absolute Maximum Ratings**.

Note 3. Do not exceed the total current value.

Note 4. Specification under conditions where the duty factor ≤ 70%.
The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I_{OH} × 0.7)/(n × 0.01)

  Example: n = 80% when I_{OH} = -10.0 mA
  Total output current of pins = (-10.0 × 0.7)/(80 × 0.01) ≈ -8.7 mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.
A current higher than the absolute maximum rating must not flow into one pin.

Caution **P10 to P15 do not output high level in N-ch open-drain mode.**

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/3)**

Item	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input voltage, high	V_{IH1}	P10 to P17 and P40 to P42	Normal input buffer	0.8 V_{DD}		V_{DD}	V
	V_{IH2}	P11, P12, P14, P15	TTL input buffer, 4.0 V ≤ V_{DD} ≤ 5.5 V	2.2		V_{DD}	V
			TTL input buffer, 3.3 V ≤ V_{DD} < 4.0 V	2.0		V_{DD}	V
			TTL input buffer, 2.4 V ≤ V_{DD} < 3.3 V	1.5		V_{DD}	V
	V_{IH3}	P121, P122, P137, EXCLK, $\overline{RESET}$		0.8 V_{DD}		V_{DD}	V
Input voltage, low	V_{IL1}	P10 to P17 and P40 to P42	Normal input buffer	0		0.2 V_{DD}	V
	V_{IL2}	P11, P12, P14, P15	TTL input buffer, 4.0 V ≤ V_{DD} ≤ 5.5 V	0		0.8	V
			TTL input buffer, 3.3 V ≤ V_{DD} < 4.0 V	0		0.5	V
			TTL input buffer, 2.4 V ≤ V_{DD} < 3.3 V	0		0.32	V
	V_{IL3}	P121, P122, P137, EXCLK, $\overline{RESET}$		0		0.2 V_{DD}	V
Output voltage, high	V_{OH1}	P10 to P17 and P40 to P42	4.0 V ≤ V_{DD} ≤ 5.5 V, T_A = -40 to +85°C, I_{OH1} = -10.0 mA	V_{DD} - 1.5			V
			4.0 V ≤ V_{DD} ≤ 5.5 V, 85°C < T_A ≤ 105°C, I_{OH1} = -3.0 mA	V_{DD} - 0.7			V
			2.7 V ≤ V_{DD} ≤ 5.5 V, I_{OH1} = -2.0 mA	V_{DD} - 0.6			V
			2.4 V ≤ V_{DD} ≤ 5.5 V, I_{OH1} = -1.5 mA	V_{DD} - 0.5			V
Output voltage, low	V_{OL1}	P10 to P17 and P40 to P42	4.0 V ≤ V_{DD} ≤ 5.5 V, T_A = -40 to +85°C, I_{OL1} = 20.0 mA			1.3	V
			4.0 V ≤ V_{DD} ≤ 5.5 V, 85°C < T_A ≤ 105°C, I_{OL1} = 8.5 mA			0.7	V
			2.7 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 3.0 mA			0.6	V
			2.7 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 1.5 mA			0.4	V
			2.4 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 0.6 mA			0.4	V

Caution The maximum V_{IH} value on P10 to P15 is V_{DD}, even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(3/3)**

Item	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Input leakage current, high	I_{LIH1}	P10 to P17, and P40 to P42	V_I = V_{DD}				1	μA
	I_{LIH2}	P137, $\overline{RESET}$	V_I = V_{DD}				1	μA
	I_{LIH3}	P121, P122 (X1, X2, EXCLK)	V_I = V_{DD}	In input port mode or when using external clock input			1	μA
				When a resonator is connected			10	μA
Input leakage current, low	I_{LIL1}	P10 to P17, and P40 to P42	V_I = V_{SS}				-1	μA
	I_{LIL2}	P137, $\overline{RESET}$	V_I = V_{SS}				-1	μA
	I_{LIL3}	P121, P122 (X1, X2, EXCLK)	V_I = V_{SS}	In input port mode or when using external clock input			-1	μA
				When a resonator is connected			-10	μA
On-chip pull-up resistance	R_U	P10 to P15, P40	V_I = V_{SS}, in input port mode		10	20	100	kΩ

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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2.3.2 Supply current characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current Note 1	IDD1	Operating mode Note 2	f_{HOCO} = 32 MHz, f_{MAIN} = 32 MHz Note 3	Basic operation	V_{DD} = 5.0 V		2.1		mA
					V_{DD} = 3.0 V		2.1		
			f_{HOCO} = 32 MHz, f_{MAIN} = 32 MHz Note 3	Normal operation	V_{DD} = 5.0 V		4.8	8.7	mA
					V_{DD} = 3.0 V		4.8	8.7	
			f_{HOCO} = 24 MHz, f_{MAIN} = 24 MHz Note 3	Normal operation	V_{DD} = 5.0 V		3.8	6.7	
					V_{DD} = 3.0 V		3.8	6.7	
			f_{HOCO} = 16 MHz, f_{MAIN} = 16 MHz Note 3	Normal operation	V_{DD} = 5.0 V		2.8	4.9	
					V_{DD} = 3.0 V		2.8	4.9	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 4, V_{DD} = 5.0 V	Normal operation	Square wave input		3.3	5.7	mA
					Resonator connection		3.5	5.8	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 4, V_{DD} = 3.0 V	Normal operation	Square wave input		3.3	5.7	
					Resonator connection		3.5	5.8	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 4, V_{DD} = 5.0 V	Normal operation	Square wave input		2.0	3.4	
					Resonator connection		2.1	3.5	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 4, V_{DD} = 3.0 V	Normal operation	Square wave input		2.0	3.4	
					Resonator connection		2.1	3.5	
			f_{MX} = 8 MHz, f_{MAIN} = 32 MHz Note 5, V_{DD} = 5.0 V	Normal operation	Square wave input		5.2	9.2	mA
					Resonator connection		5.3	9.3	
			f_{MX} = 8 MHz, f_{MAIN} = 32 MHz Note 5, V_{DD} = 3.0 V	Normal operation	Square wave input		5.2	9.2	
					Resonator connection		5.3	9.3	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 5, V_{DD} = 5.0 V	Normal operation	Square wave input		5.1	9.1	
					Resonator connection		5.2	9.2	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 5, V_{DD} = 3.0 V	Normal operation	Square wave input		5.1	9.1	
					Resonator connection		5.2	9.2	

Note 1. Total current flowing into V_{DD}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD} or V_{SS}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

Note 2. The relationship between the operation voltage range and the CPU operating frequency is as below.
2.7 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 16 MHz

Note 3. When the high-speed system clock is stopped

Note 4. When the high-speed on-chip oscillator and the PLL are stopped

Note 5. When the high-speed on-chip oscillator is stopped and the PLL is operating

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{HOCO}: High-speed on-chip oscillator clock frequency

Remark 3. f_{MAIN}: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is T_A = 25°C

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(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/2)**

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Supply current Note 1	I_{DD2} Note 2	HALT mode Note 3	f_{HOCO} = 32 MHz, f_{MAIN} = 32 MHz Note 4	V_{DD} = 5.0 V		0.54	3.67	mA
				V_{DD} = 3.0 V		0.54	3.67	
			f_{HOCO} = 24 MHz, f_{MAIN} = 24 MHz Note 4	V_{DD} = 5.0 V		0.44	2.85	
				V_{DD} = 3.0 V		0.44	2.85	
			f_{HOCO} = 16 MHz, f_{MAIN} = 16 MHz Note 4	V_{DD} = 5.0 V		0.40	2.08	
				V_{DD} = 3.0 V		0.40	2.08	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 5, V_{DD} = 5.0 V	Square wave input		0.28	2.45	mA
				Resonator connection		0.49	2.57	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 5, V_{DD} = 3.0 V	Square wave input		0.28	2.45	
				Resonator connection		0.49	2.57	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 5, V_{DD} = 5.0 V	Square wave input		0.19	1.28	
				Resonator connection		0.30	1.36	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 5, V_{DD} = 3.0 V	Square wave input		0.19	1.28	
				Resonator connection		0.30	1.36	
			f_{MX} = 8 MHz, f_{MAIN} = 32 MHz Note 6, V_{DD} = 5.0 V	Square wave input		0.91	4.17	mA
				Resonator connection		1.01	4.27	
			f_{MX} = 8 MHz, f_{MAIN} = 32 MHz Note 6, V_{DD} = 3.0 V	Square wave input		0.91	4.17	
				Resonator connection		1.01	4.27	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 6, V_{DD} = 5.0 V	Square wave input		0.76	3.27	
				Resonator connection		0.86	3.37	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 6, V_{DD} = 3.0 V	Square wave input		0.76	3.27	
				Resonator connection		0.86	3.37	
	I_{DD3} Note 7	STOP mode	T_A = -40°C			0.38	1.14	µA
			T_A = +25°C			0.50	1.14	
			T_A = +50°C			0.66	4.52	
			T_A = +70°C			1.04	7.98	
			T_A = +85°C			2.92	16.0	
			T_A = +105°C			11.0	100.0	

Note 1. Total current flowing into V_{DD}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD} or V_{SS}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during writing to the data flash.

Note 2. During HALT instruction execution from flash memory

Note 3. The relationship between the operation voltage range and the CPU operating frequency is as below.
2.7 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 16 MHz

Note 4. When the high-speed system clock is stopped

Note 5. When the high-speed on-chip oscillator and the PLL are stopped

Note 6. When high-speed on-chip oscillator is stopped and the PLL is operating

Note 7. The MAX. value includes the leakage current in STOP mode.

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{HOCO}: High-speed on-chip oscillator clock frequency

Remark 3. f_{MAIN}: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is T_A = 25°C, except the operation in STOP mode.

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• Peripheral functions

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I_{FIL} Note 1				0.20		μA
RTC operating current	I_{RTC} Notes 1, 2, 3	f_{MX} = 4 MHz, RTCCL = 00H (f_{MX}/122)			22		μA
Interval timer operating current	I_{IT} Notes 1, 2, 4	f_{MX} = 4 MHz, RTCCL = 00H (f_{MX}/122)			22		μA
Watchdog timer operating current	I_{WDT} Notes 1, 5, 6	f_{IL} = 15 kHz			0.22		μA
LVD operating current	I_{LVD} Notes 1, 7				0.08		μA
Self-programming operating current	I_{FSP} Notes 1, 8				2.50	12.20	mA
BGO operating current	I_{BGO} Notes 1, 9				2.50	12.20	mA
SNOOZE operating current	I_{SNOZ} Note 1	A/D converter operation Notes 10,	The mode is performed		0.50	1.10	mA
			During A/D conversion, AV_{DD} = V_{DD} = 3.0 V		1.20	2.04	
		Simplified SPI(CSI)/UART operation			0.70	1.54	
		DTC operation			3.10		

Note 1. Current flowing to V_{DD}

Note 2. When the high-speed on-chip oscillator is stopped

Note 3. Current flowing only to the real-time clock (RTC). The supply current of the RL78 microcontrollers is the sum of the values of either I_{DD1} or I_{DD2}, and I_{RTC}, when the real-time clock is operating in operation mode or HALT mode.

Note 4. Current flowing only to the interval timer. The supply current of the RL78 microcontrollers is the sum of the values of either I_{DD1} or I_{DD2}, and I_{IT}, when the interval timer is operating in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, also add I_{FIL}.

Note 5. When the high-speed on-chip oscillator and high-speed system clock are stopped.

Note 6. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{WDT} when the watchdog timer is operating.

Note 7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{LVD} when the LVD circuit is operating.

Note 8. Current flowing during self-programming

Note 9. Current flowing during writing to the data flash

Note 10. The current flowing into the AV_{DD} is included.

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{IL}: Low-speed on-chip oscillator clock frequency

Remark 3. The temperature condition for the TYP. value is T_A = 25°C

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• AFE functions

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
24-bit ΔΣ A/D converter operating current	I_{DSAD}	Normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS I_{OUT} = 0 mA		0.94	1.46	mA
		Low power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS I_{OUT} = 0 mA		0.60	0.91	mA
10-bit A/D converter operating current	I_{ADC}	During conversion at the highest speed Notes 1, 2 AV_{DD} = 5.0 V		1.30	1.70	mA
Configurable amplifier operating current	I_{AMP}	Normal mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier I_L = 0 mA Per channel		0.13	0.24	mA
		High-speed mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier I_L = 0 mA Per channel		0.30	0.45	mA
12-bit D/A converter operating current	I_{DAC}	When AV_{DD} is selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR and internal reference voltage (VREFDA)		0.61	0.97	mA

Note 1. Current flowing to AV_{DD}

Note 2. Current flowing only to the circuits that operate shown in the Conditions column.

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2.4 AC Characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

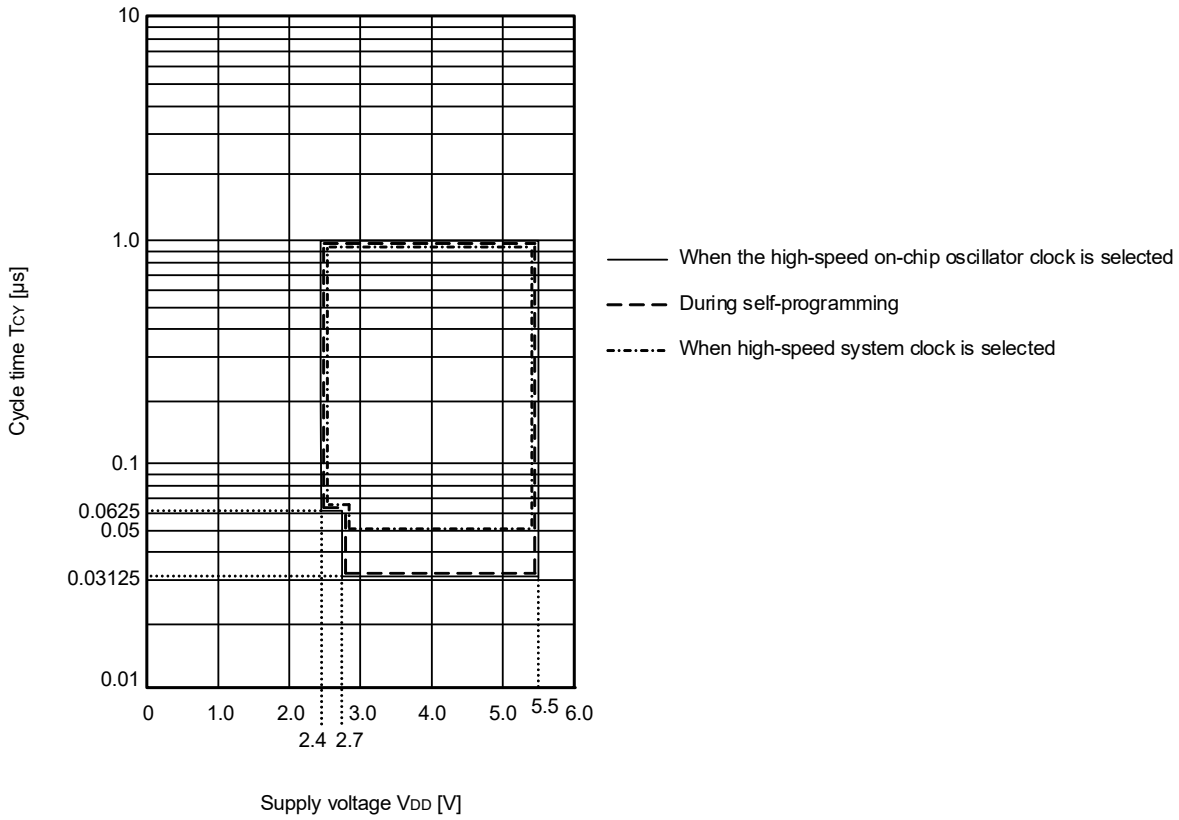
Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T_{CY}	Main system clock (f_{MAIN}) operation	2.7 V ≤ V_{DD} ≤ 5.5 V	0.03125		1	µs
			2.4 V ≤ V_{DD} < 2.7 V	0.0625		1	µs
		In the self-programming mode	2.7 V ≤ V_{DD} ≤ 5.5 V	0.03125		1	µs
			2.4 V ≤ V_{DD} < 2.7 V	0.0625		1	µs
External system clock frequency	f_{EX}	2.7 V ≤ V_{DD} ≤ 5.5 V		1.0		20.0	MHz
		2.4 V ≤ V_{DD} < 2.7 V		1.0		16.0	MHz
External system clock input high-level width, low-level width	t_{EXH}, t_{EXL}	2.7 V ≤ V_{DD} ≤ 5.5 V		24			ns
		2.4 V ≤ V_{DD} < 2.7 V		30			ns
TI00 to TI03, TI10, TI11 input high-level width, low-level width	t_{TIH}, t_{TIL}			1/f_{MCK} + 10			ns
Timer RJ input cycle	f_C	TRJIO0	2.7 V ≤ V_{DD} ≤ 5.5 V	100			ns
			2.4 V ≤ V_{DD} < 2.7 V	300			ns
Timer RJ input high-level width, low-level width	t_{TJIH}, t_{TJIL}	TRJIO0	2.7 V ≤ V_{DD} ≤ 5.5 V	40			ns
			2.4 V ≤ V_{DD} < 2.7 V	120			ns
Timer RG input high-level width, low-level width	t_{TGIH}, t_{TGIL}	TRGIOA, TRGIOB		2.5/f_{CLK}			ns
TO00 to TO03, TO10, TO11, TRJIO0, TRJO0, TRGIOA, TRGIOB output frequency	f_{TO}		4.0 V ≤ V_{DD} ≤ 5.5 V			16	MHz
			2.7 V ≤ V_{DD} ≤ 4.0 V			8	MHz
			2.4 V ≤ V_{DD} < 2.7 V			4	MHz
PCLBUZ0 output frequency	f_{PCL}		4.0 V ≤ V_{DD} ≤ 5.5 V			16	MHz
			2.7 V ≤ V_{DD} ≤ 4.0 V			8	MHz
			2.4 V ≤ V_{DD} < 2.7 V			4	MHz
Interrupt input high-level width, low-level width	t_{INTH}, t_{INTL}	INTP1 to INTP7		1			µs
$\overline{\text{RESET}}$ low-level width	t_{RSL}			10			µs

Remark f_{MCK}: Timer array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

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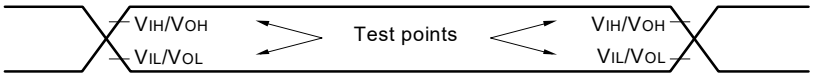
Minimum Instruction Execution Time During Main System Clock Operation

TCY vs VDD

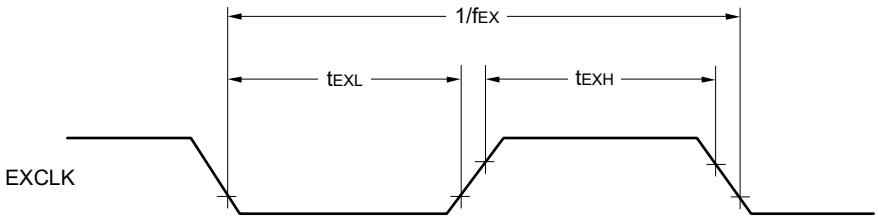


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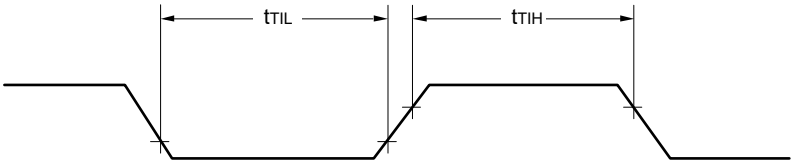
AC Timing Test Points



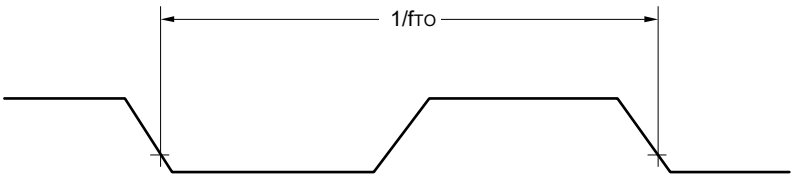
External System Clock Timing



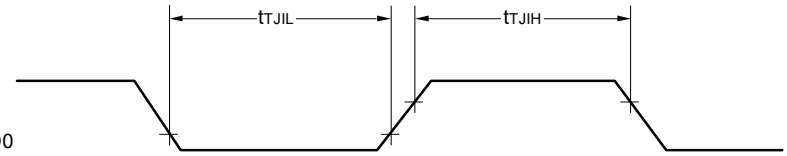
TI/TO Timing



TI00 to TI03, TI10, TI11

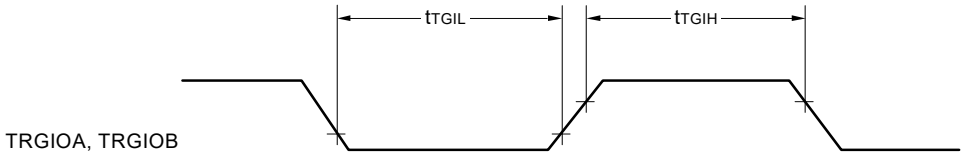


TO00 to TO03, TO10, TI11,
TRJIO0, TRJO0,
TRGIOA, TRGIOB

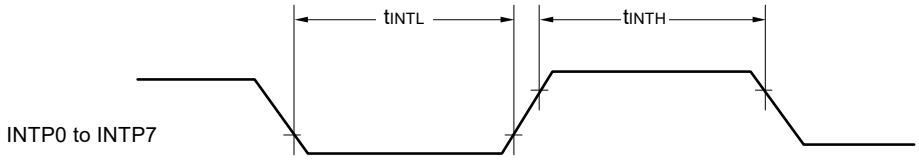


TRJIO0

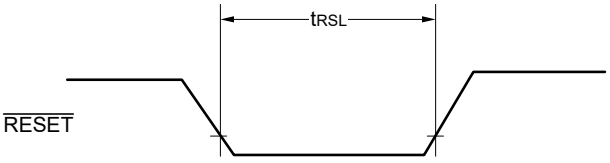
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Interrupt Request Input Timing



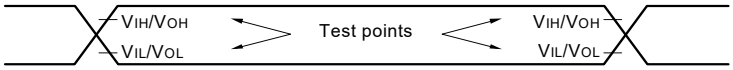
$\overline{\text{RESET}}$ Input Timing



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2.5 Peripheral Functions Characteristics

AC Timing Test Points



2.5.1 Serial array unit

(1) During communication at same potential (UART mode)

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

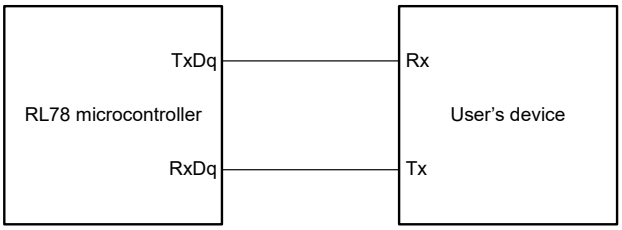
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate Note 1				fMCK/12	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 2		2.6	Mbps

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

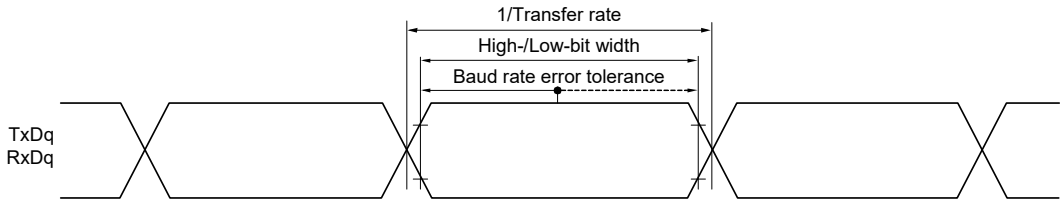
Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:
32 MHz (2.7 V ≤ VDD ≤ 5.5 V)
16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

UART mode connection diagram (during communication at same potential)



UART mode bit width (during communication at same potential) (reference)



Remark 1. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 2. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03))

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(2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t_{KCY1}	$t_{KCY1} \geq 4/f_{CLK}$	2.7 V ≤ V_{DD} ≤ 5.5 V	250		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	500		ns
SCKp high-/low-level width	t_{KH1}, t_{KL1}	4.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 24		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 36		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 76		ns
SIp setup time (to SCKp↑) Note 1	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V		66		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		66		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		113		ns
SIp hold time (from SCKp↑) Note 1	t_{KSI1}			38		ns
Delay time from SCKp↓ to SOp output Note 2	t_{KSO1}	C = 30 pF Note 3			50	ns

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

Remark 2. f_{MCK}: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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(3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time Note 1	t_{KCY2}	4.0 V ≤ V_{DD} ≤ 5.5 V	20 MHz < f_{MCK}	16/f_{MCK}		ns
			f_{MCK} ≤ 20 MHz	12/f_{MCK}		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V	16 MHz < f_{MCK}	16/f_{MCK}		ns
			f_{MCK} ≤ 16 MHz	12/f_{MCK}		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		12/f_{MCK} and 1000		ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	4.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 14		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 16		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 36		ns
SIp setup time (to SCKp↑) Note 2	t_{SIK2}	2.7 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 40		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 60		ns
SIp hold time (from SCKp↑) Note 2	t_{KSI2}			1/f_{MCK} + 62		ns
Delay time from SCKp↓ to SOp output Note 3	t_{KSO2}	C = 30 pF Note 4	2.7 V ≤ V_{DD} ≤ 5.5 V		2/f_{MCK} + 66	ns
			2.4 V ≤ V_{DD} ≤ 5.5 V		2/f_{MCK} + 113	ns
$\overline{SSI00}$ setup time	t_{SSIK}	DAPmn = 0	2.7 V ≤ V_{DD} ≤ 5.5 V	240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	400		ns
		DAPmn = 1	2.7 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 400		ns
$\overline{SSI00}$ hold time	t_{KSSI}	DAPmn = 0	2.7 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 400		ns
		DAPmn = 1	2.7 V ≤ V_{DD} ≤ 5.5 V	240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	400		ns

Note 1. The maximum transfer rate in the SNOOZE mode is 1 Mbps.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SOp output lines.

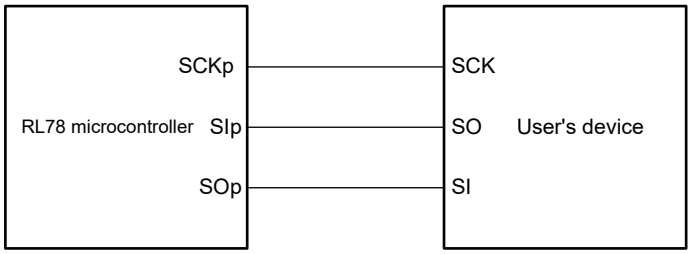
Caution Select the normal input buffer for the SIp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

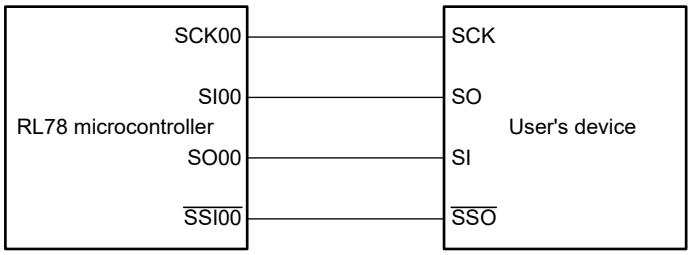
Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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Simplified SPI(CSI) mode connection diagram (during communication at same potential)



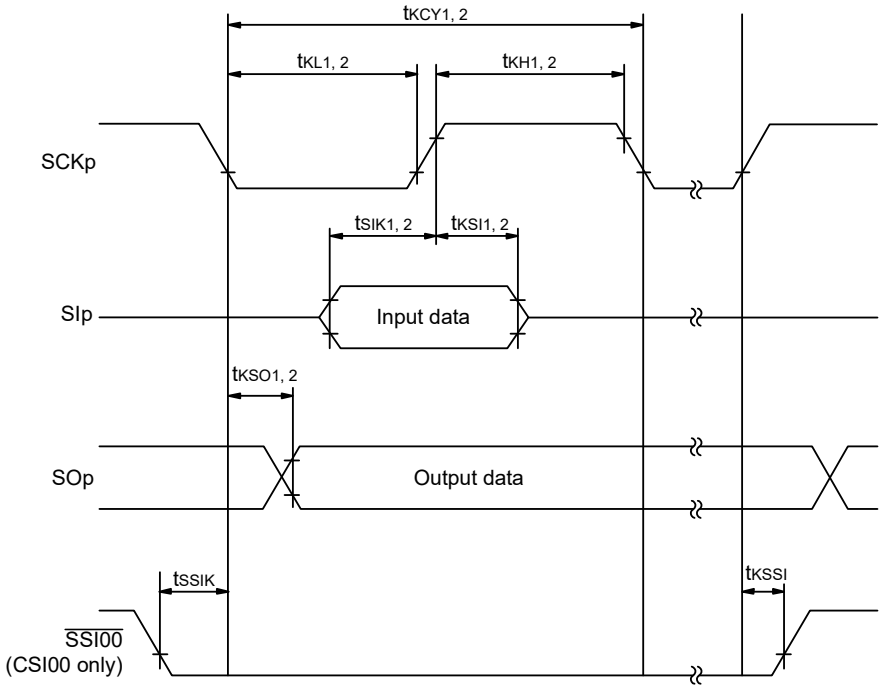
Simplified SPI(CSI) mode connection diagram (during communication at same potential)
(Slave Transmission of slave select input function (CSI00))



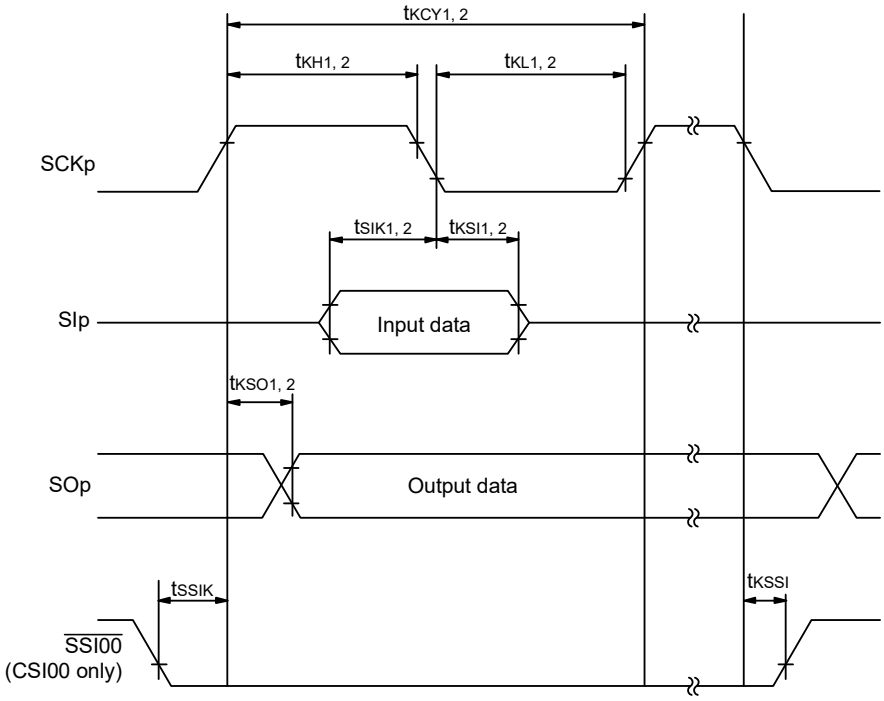
Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)
Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

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Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)
Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

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(4) During communication at same potential (simplified I²C mode)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f_{SCL}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ		100 Note 1	kHz
Hold time when SCLr = "L"	t_{LOW}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	4600		ns
Hold time when SCLr = "H"	t_{HIGH}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	4600		ns
Data setup time (reception)	$t_{SU:DAT}$	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 220 Note 2		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	1/f_{MCK} + 580 Note 2		ns
Data hold time (transmission)	$t_{HD:DAT}$	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	0	1420	ns

Note 1. The value must also be equal to or less than f_{MCK}/4.

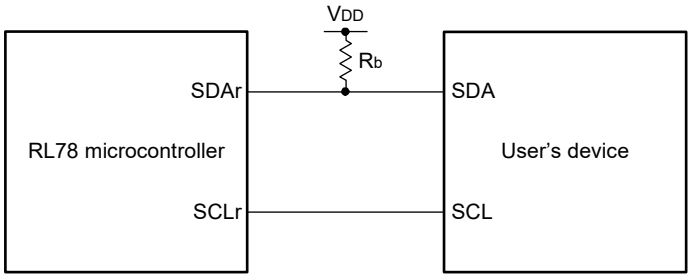
Note 2. Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

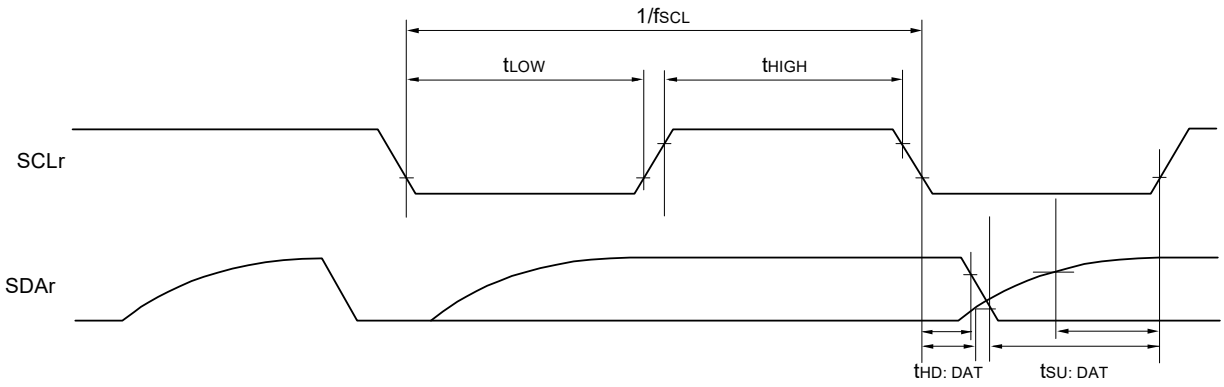
(Remarks are listed on the next page.)

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Simplified I²C mode connection diagram (during communication at same potential)



Simplified I²C mode serial transfer timing (during communication at same potential)



Remark 1. Rb [Ω]: Communication line (SDAr) pull-up resistance, Cb [F]: Communication line (SDAr, SCLr) load capacitance

Remark 2. r: IIC number (r = 00, 01), g: PIM number (g = 1), h: POM number (h = 1)

Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0, 1), mn = 00, 01)

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(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
Transfer rate		Reception	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.6	Mbps
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.6	Mbps
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.6	Mbps

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (f_{CLK}) are:
32 MHz (2.7 V ≤ V_{DD} ≤ 5.5 V)
16 MHz (2.4 V ≤ V_{DD} ≤ 5.5 V)

Caution **Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.**

Remark 1. V_b [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01)

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(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/2)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		Note 1	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 1.4 kΩ, V_b = 2.7 V		2.6 Note 2	Mbps
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		Note 3	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 2.7 kΩ, V_b = 2.3 V		1.2 Note 4	Mbps
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		Note 5	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 5.5 kΩ, V_b = 1.6 V		0.43 Note 6	Mbps

Note 1. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ V_{DD} ≤ 5.5 V and 2.7 V ≤ V_b ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 2. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

Note 3. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V_{DD} < 4.0 V and 2.3 V ≤ V_b ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 4. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

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Note 5. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.
Expression for calculating the transfer rate when 2.4 V ≤ V_{DD} < 3.3 V and 1.6 V ≤ V_b ≤ 2.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

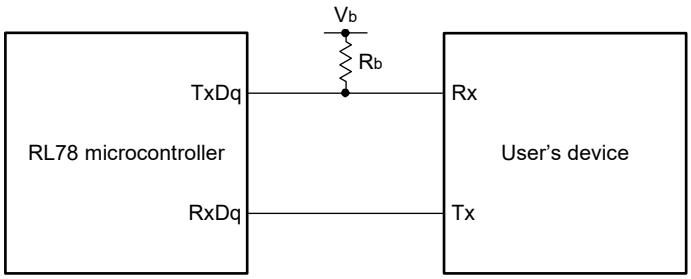
Note 6. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

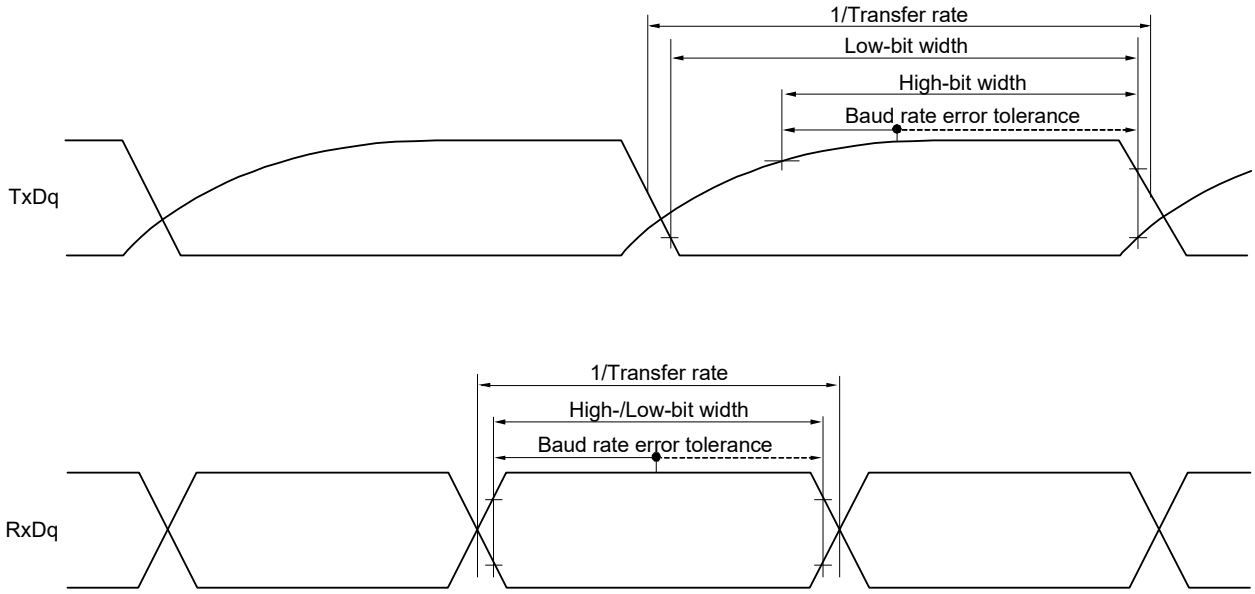
(Remarks are listed on the next page.)

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UART mode connection diagram (during communication at different potential)



UART mode bit width (during communication at different potential) (reference)



Remark 1. Rb [Ω]: Communication line (TxDq) pull-up resistance,
Cb [F]: Communication line (TxDq) load capacitance, Vb [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/3)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t_{KCY1}	$t_{KCY1} \geq 4/f_{CLK}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	600		ns
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	1000		ns
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	2300		ns
SCKp high-level width	t_{KH1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		t_{KCY1}/2 - 150		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		t_{KCY1}/2 - 340		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		t_{KCY1}/2 - 916		ns
SCKp low-level width	t_{KL1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		t_{KCY1}/2 - 24		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		t_{KCY1}/2 - 36		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		t_{KCY1}/2 - 100		ns

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) (2/3)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SIp setup time (to SCKp↑) Note	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	162		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	354		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	958		ns
SIp hold time (from SCKp↑) Note	t_{KSI1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	38		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	38		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	38		ns
Delay time from SCKp↓ to SOp output Note	t_{KSO1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		200	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		390	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		966	ns

Note When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(3/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SIp setup time (to SCKp↓) Note	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	88		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	88		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	220		ns
SIp hold time (from SCKp↓) Note	t_{KSI1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	38		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	38		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	38		ns
Delay time from SCKp↑ to SOp output Note	t_{KSO1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		50	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		50	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		50	ns

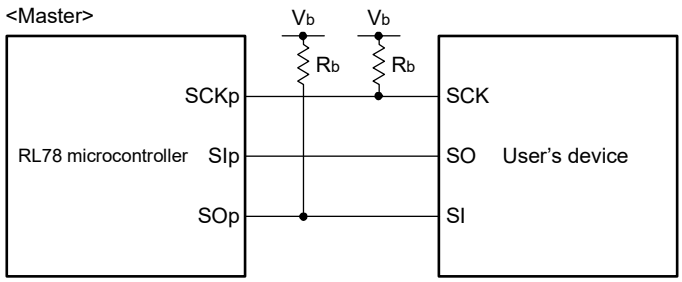
Note When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

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Simplified SPI(CSI) mode connection diagram (during communication at different potential



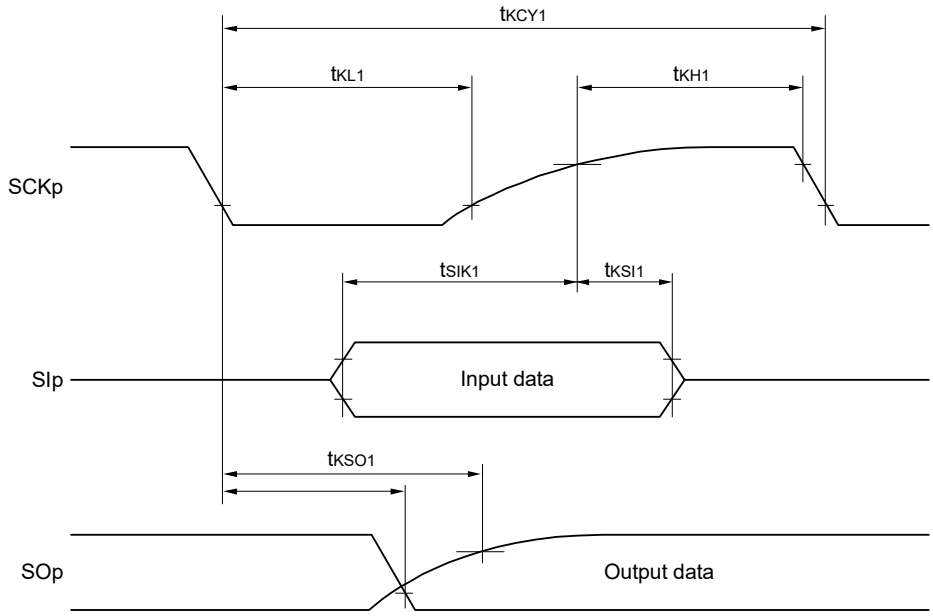
Remark 1. Rb [Ω]: Communication line (SCKp, SOp) pull-up resistance, Cb [F]: Communication line (SCKp, SOp) load capacitance, Vb [V]: Communication line voltage

Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

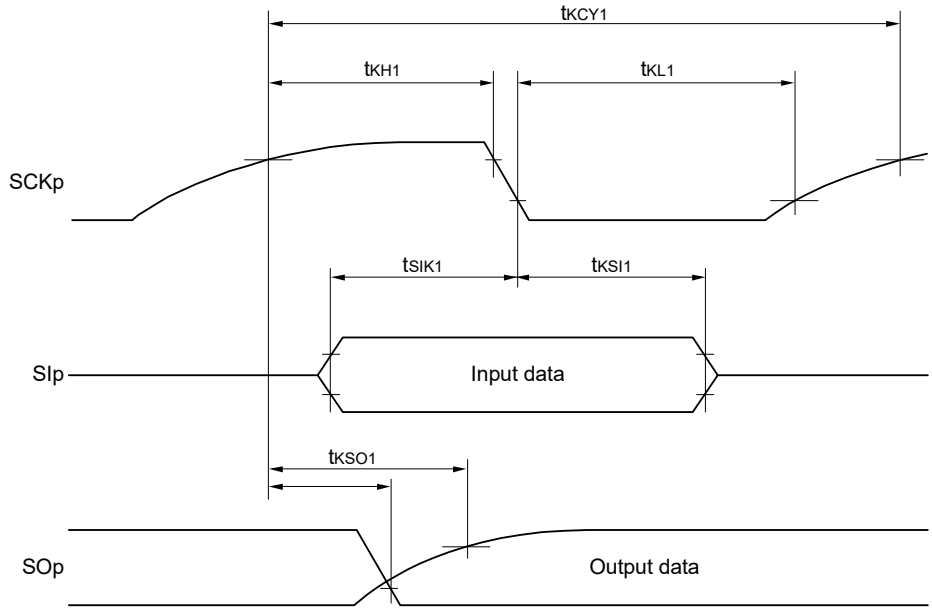
Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

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(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time Note 1	t_{KCY2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V	24 MHz < f_{MCK}	28/f_{MCK}		ns
			20 MHz < f_{MCK} ≤ 24 MHz	24/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 20 MHz	20/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	16/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	12/f_{MCK}		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V	24 MHz < f_{MCK}	40/f_{MCK}		ns
			20 MHz < f_{MCK} ≤ 24 MHz	32/f_{MCK}		ns
			16 MHz < f_{MCK} ≤ 20 MHz	28/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 16 MHz	24/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	16/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	12/f_{MCK}		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V	24 MHz < f_{MCK}	96/f_{MCK}		ns
			20 MHz < f_{MCK} ≤ 24 MHz	72/f_{MCK}		ns
			16 MHz < f_{MCK} ≤ 20 MHz	64/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 16 MHz	52/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	32/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	20/f_{MCK}		ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		t_{KCY2}/2 - 24		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		t_{KCY2}/2 - 36		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		t_{KCY2}/2 - 100		ns
SIp setup time (to SCKp↑) Note 2	t_{SIK2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		1/f_{MCK} + 40		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		1/f_{MCK} + 40		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		1/f_{MCK} + 60		ns
SIp hold time (from SCKp↑) Note 2	t_{KSI2}			1/f_{MCK} + 62		ns
Delay time from SCKp↓ to SOp output Note 3	t_{KSO2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ			2/f_{MCK} + 240	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ			2/f_{MCK} + 428	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ			2/f_{MCK} + 1146	ns

(Notes, Cautions, and Remarks are listed on the next page.)

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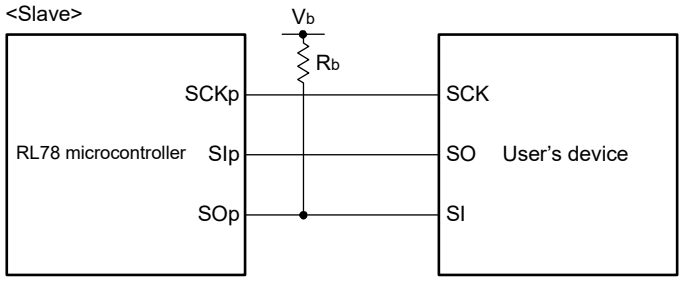
Note 1. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp and SCKp pins, and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

Simplified SPI(CSI) mode connection diagram (during communication at different potential)



Remark 1. R_b [Ω]: Communication line (SOp) pull-up resistance, C_b [F]: Communication line (SOp) load capacitance, V_b [V]: Communication line voltage

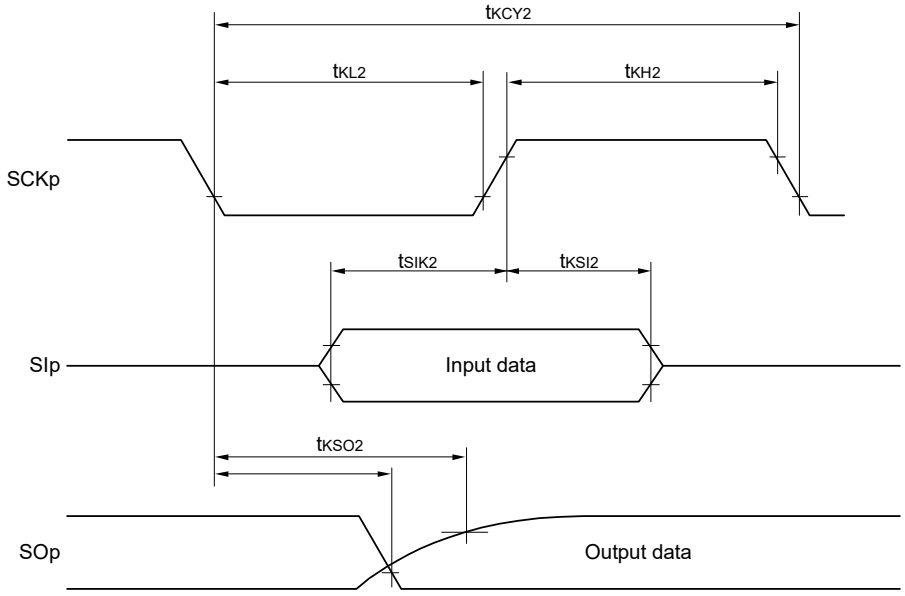
Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0 , 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))

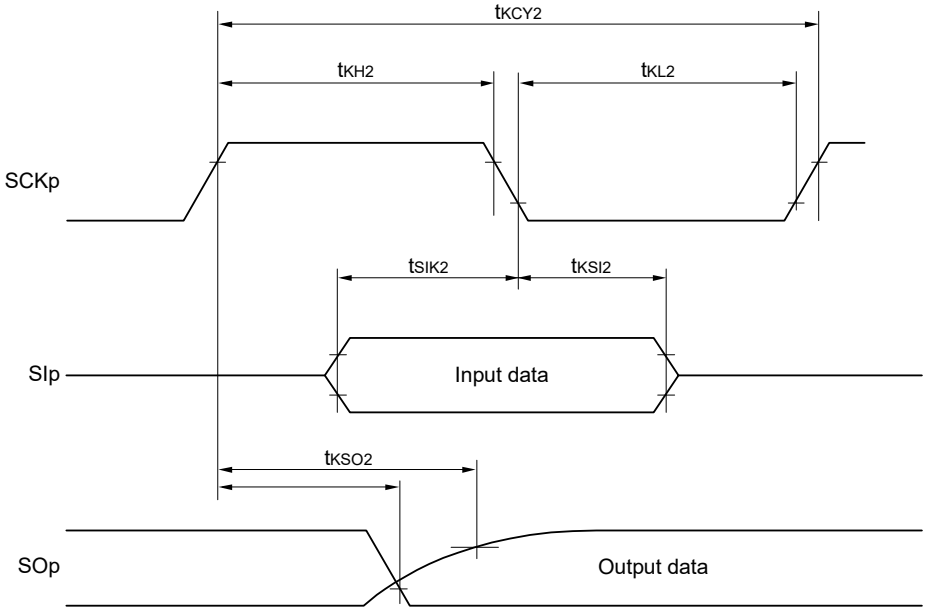
Remark 4. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

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Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

Remark 2. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

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(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f_{SCL}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ		100 Note 1	kHz
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ		100 Note 1	kHz
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ		100 Note 1	kHz
Hold time when SCLr = “L”	t_{LOW}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	4600		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	4600		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	4600		ns
Hold time when SCLr = “H”	t_{HIGH}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	620		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	500		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	2700		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	2400		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	1830		ns

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(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I^2C mode)

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) (2/2)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Data setup time (reception)	$t_{SU:DAT}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 340 Note 2		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 340 Note 2		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	1/f_{MCK} + 760 Note 2		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	1/f_{MCK} + 760 Note 2		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	1/f_{MCK} + 570 Note 2		ns
Data hold time (transmission)	$t_{HD:DAT}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	0	1420	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	0	1420	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	0	1215	ns

Note 1. The value must also be equal to or less than f_{MCK}/4.

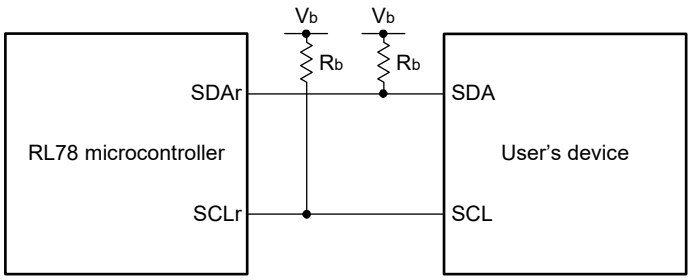
Note 2. Set the f_{MCK} value to keep the hold time of SCLr = “L” and SCLr = “H”.

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

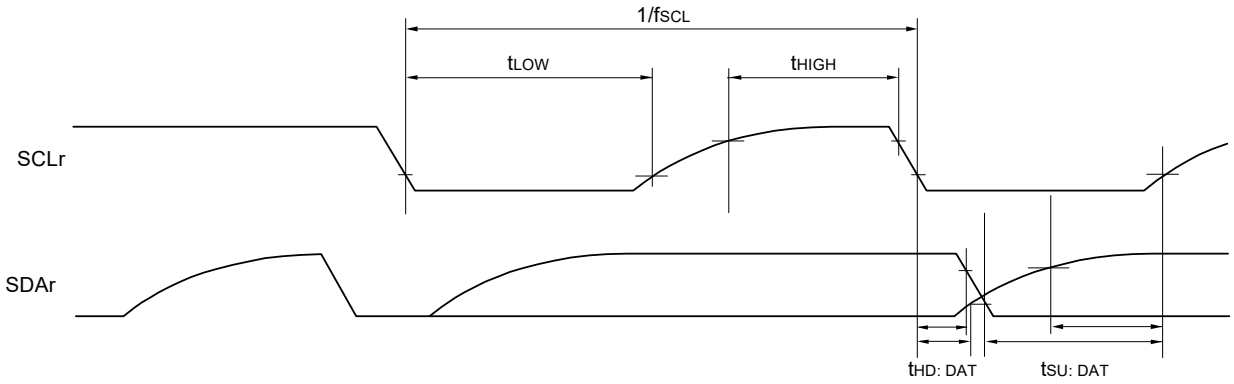
(Remarks are listed on the next page.)

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Simplified I²C mode connection diagram (during communication at different potential)



Simplified I²C mode serial transfer timing (during communication at different potential)



Remark 1. Rb [Ω]: Communication line (SDAr, SCLr) pull-up resistance, Cb [F]: Communication line (SDAr, SCLr) load capacitance, Vb [V]: Communication line voltage

Remark 2. r: IIC number (r = 00, 01), g: PIM, POM number (g = 1)

Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0), mn = 00, 01)

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2.6 Analog Characteristics

2.6.1 Programmable gain instrumentation amplifier and 24-bit ΔΣ A/D converter

(1) Analog input in differential input mode

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Full-scale differential input voltage range	V_{ID}	V_{ID} = (PGAxP - PGAxN) (x = 0 to 3)		± 800 /G_{TOTAL}		mV
Input voltage range	V_I	Each of PGAxP and PGAxN pins (x = 0 to 3)	0.2		1.8	V
Common mode input voltage	V_{COM}	$dOFR$ = 0 mV	0.2+(|V_{ID}|x G_{SET1})/2		1.8-(|V_{ID}|x G_{SET1})/2	V
Input bias current	I_{IN}	V_I = 1.0 V			±50	nA
Input offset current	I_{INOFR}	V_I = 1.0 V			±20	nA

(2) Analog input in single-ended input mode

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage range	V_I	Each of PGAxP and PGAxN pins (x = 0 to 3) G_{SET1} = 1, G_{SET2} = 1	0.2		1.8	V
Input bias current	I_{IN}	V_I = 1.0 V			±50	nA

(3) Programmable gain instrumentation amplifier and 24-bit ΔΣ A/D converter

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used, in differential input mode) **(1/2)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES				24	bit
Sampling frequency	f_{S1}	Normal mode		1		MHz
	f_{S2}	Low power mode		0.125		MHz
Output data rate	f_{DATA1}	Normal mode	0.48828		15.625	ksps
	f_{DATA2}	Low power mode	61.03615		1953.125	sps
Gain setting range	G_{TOTAL}	G_{TOTAL} = G_{SET1} × G_{SET2}	1		64	V/V
1st gain setting range	G_{SET1}	In differential input mode only		1, 2, 3, 4, 8		V/V
2nd gain setting range	G_{SET2}	In differential input mode only		1, 2, 4, 8		V/V
Offset adjustment bit range	$dOFFB$			5		bit
Offset adjustment range	$dOFR$	Referred to input	-164/G_{SET1}		+164/G_{SET1}	mV
Offset adjustment steps	$dOFS$	Referred to input		11/G_{SET1}		mV

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(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, d_{OFR} = 0 mV, V_{COM} = 1.0 V, external clock input used, in differential input mode) (2/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Gain error	E_G	T_A = 25°C G_{SET1} = 1, G_{SET2} = 1 Excluding SBIAS error		±0.2	±2.7	%
		T_A = 25°C G_{SET1} = 8, G_{SET2} = 4 Excluding SBIAS error		±0.1		%
Gain drift Note	dE_G	G_{SET1} = 1, G_{SET2} = 1 Excluding SBIAS drift		(5.6)	(22.0)	ppm/°C
		G_{SET1} = 8, G_{SET2} = 4 Excluding SBIAS drift		(9.1)		ppm/°C
Offset error	E_{OS}	T_A = 25°C G_{SET1} = 1, G_{SET2} = 1 Referred to input		±0.32	±2.90	mV
		T_A = 25°C G_{SET1} = 8, G_{SET2} = 4 Referred to input		±0.03		mV
Offset drift Note	dE_{OS}	G_{SET1} = 1, G_{SET2} = 1 Referred to input		(±0.02)	(±6.00)	µV/°C
		G_{SET1} = 8, G_{SET2} = 4 Referred to input		(±0.02)		µV/°C
SND ratio	SNDR	G_{SET1} = 1, G_{SET2} = 1, f_{IN} = 50 Hz Normal mode, pin = -1 dBFS	(82)	(85)		dB
		G_{SET1} = 8, G_{SET2} = 4, f_{IN} = 50 Hz Normal mode, pin = -1 dBFS	(73)	(80)		dB
Noise	Vn	G_{SET1} = 1, G_{SET2} = 1, OSR = 2048		(13)		µVRms
		G_{SET1} = 8, G_{SET2} = 4, OSR = 2048		(0.6)		µVRms
Integral non-linearity error	INL	G_{SET1} = 1, G_{SET2} = 1, OSR = 2048		(±10)		ppmFS
Common mode rejection ratio	CMRR	V_{COM} = 1.0±0.8 V, fin = 50 Hz G_{SET1} = 1, G_{SET2} = 1 Differential input mode	(72)	(90)		dB
Power supply rejection ratio	PSRR	AV_{DD} = 2.7 to 5.5 V G_{SET1} = 1, G_{SET2} = 1 Differential input mode		(85)		dB
ΔΣ A/D converter input clock frequency	f_{ADC}		3.8	4	4.2	MHz

Note Calculate the gain drift and offset drift by using the following expression (for 105°C products):
For gain drift: (MAX(E_G($T_{(-40)}$ to $T_{(105)}$)) - MIN(E_G($T_{(-40)}$ to $T_{(105)}$))) / (105°C -(-40°C))
For offset drift: (MAX(E_{OS}($T_{(-40)}$ to $T_{(105)}$)) - MIN(E_{OS}($T_{(-40)}$ to $T_{(105)}$))) / (105°C -(-40°C))
MAX(E_G($T_{(-40)}$ to $T_{(105)}$)): The maximum value of gain error when the temperature range is -40°C to 105°C
MIN(E_G($T_{(-40)}$ to $T_{(105)}$)): The minimum value of gain error when the temperature range is -40°C to 105°C
MAX(E_{OS}($T_{(-40)}$ to $T_{(105)}$)): The maximum value of offset error when the temperature range is -40°C to 105°C
MIN(E_{OS}($T_{(-40)}$ to $T_{(105)}$)):The minimum value of offset error when the temperature range is -40°C to 105°C

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

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2.6.2 Sensor power supply (SBIAS)

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, C_{OUT} = 0.22 µF, V_{OUT} = 1.0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage range	V_{OUT}		0.5		2.2	V
Output voltage setting steps	V_{STEP}			0.1		V
Output voltage precision	V_A	I_{OUT} = 1 mA	(-3)		(+3)	%
Maximum output current	I_{OUT}		5			mA
Short circuit current	I_{SHORT}	V_{OUT} = 0 V		40	65	mA
Load regulation	L_R	1 mA ≤ I_{OUT} ≤ 5 mA			(15)	mV
Power supply rejection ratio	PSRR	AV_{DD} = 5.0 V + 0.1 $V_{pp\ ripple}$ f = 100 Hz, I_{OUT} = 2.5 mA	(45)	(50)		dB

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

2.6.3 Temperature sensor

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature coefficient for sensor	TC_{SNS}			(756)		µV/°C
Sensor output voltage	V_{TEMP}	T_A = 25°C		226.4		mV

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

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2.6.4 A/D converter characteristics

(1) When positive reference voltage (+) = AV_{DD} (ADREFP1 = 0, ADREFP0 = 0), negative reference voltage (-) = AV_{SS} (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = AV_{DD}, negative reference voltage (-) = AV_{SS})

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error Note 1	AINL	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V		1.2	±6.5	LSB
			2.7 V ≤ AV_{DD} ≤ 5.5 V		1.2	±7.0	LSB
Conversion time	t_{CONV}	10-bit resolution	4.0 V ≤ AV_{DD} ≤ 5.5 V	2.125		39	µs
			2.7 V ≤ AV_{DD} ≤ 5.5 V	3.1875		39	µs
Zero-scale error Notes 1, 2	E_{ZS}	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±0.50	%FSR
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Full-scale error Notes 1, 2	E_{FS}	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±0.50	%FSR
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Integral linearity error Note 1	ILE	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±3.5	LSB
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±4.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±2.0	LSB
Analog input voltage	V_{AIN}	ANI0 to ANI9		AV_{SS}		AV_{DD}	V

Note 1. Excludes quantization error (±1/2 LSB).
Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Caution The number of pins depends on the product. For details, see a list of pin functions.

(2) When positive reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), negative reference voltage (-) = AV_{SS} (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = V_{BGR}, negative reference voltage (-) = AV_{SS})

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	t_{CONV}	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V	17		39	µs
Zero-scale error Notes 1, 2	E_{ZS}	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Integral linearity error Note 1	ILE	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±2.0	LSB
Differential linearity error Note 1	DLE	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±1.0	LSB
Internal reference voltage (+)	V_{BGR}	2.7 V ≤ AV_{DD} ≤ 5.5 V		V_{BGR} Note 3			V
Analog input voltage	V_{AIN}	ANI0 to ANI9		0		V_{BGR}	V

Note 1. Excludes quantization error (±1/2 LSB).
Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.
Note 3. See the Internal reference voltage characteristics.

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2.6.5 12-bit D/A converter

(1) When positive reference voltage (+) = AV_{DD} (DACVRF = 0)

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = AV_{DD})

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	DARES				(12)	bit
Output voltage range	DAOUT	12-bit resolution	0.35		AV_{DD}-0.47	V
Integral non-linearity error	DAILE	12-bit resolution			±4.0	LSB
Differential non-linearity error	DADLE	12-bit resolution			±1.0	LSB
Offset error	DAErr	12-bit resolution			±30	mV
Gain error	DAEG	12-bit resolution			±20	mV
Settling time	DAtset	12-bit resolution, C_L = 50 pF, R_L = 10 kΩ			(60)	μs

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

(2) When positive reference voltage (+) = internal reference voltage (DACVRF = 1)

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = VREFDA)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	DARES				(8)	bit
Internal reference voltage	VREFDA	8-bit resolution	1.34	1.45	1.54	V
Output voltage range	DAOUT	8-bit resolution	0.35		VREFDA	V
Integral non-linearity error	DAILE	8-bit resolution			±1.0	LSB
Differential non-linearity error	DADLE	8-bit resolution			±1.0	LSB
Offset error	DAErr	8-bit resolution			±30	mV
Gain error	DAEG	8-bit resolution			±20	mV
Settling time	DAtset	8-bit resolution, C_L = 50 pF, R_L = 10 kΩ			(60)	μs

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.
Remark 3. Offset error and gain error do not include error in the internal reference voltage.

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2.6.6 Configurable amplifier

(T_A = -40 to +105°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, V_{COM} = 1/2 AV_{DD}, internally connected voltage follower)

AMP0 configuration SW setting: Positive (+) pin = ANX1, negative (-) pin = ANX0

AMP1 configuration SW setting: Positive (+) pin = ANX3, negative (-) pin = ANX2

AMP2 configuration SW setting: Positive (+) pin = ANX5, negative (-) pin = ANX4

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage	V_{IN}		AV_{SS}		AV_{DD}	V
Output voltage	V_{OL}	I_L= -1 mA, AV_{DD} = 2.7 to 5.5 V		AV_{SS} +0.02	AV_{SS} +0.07	V
	V_{OH}	I_L= 1 mA, AV_{DD} = 2.7 to 5.5 V	AV_{DD} -0.15	AV_{DD} -0.02		V
Maximum output current	I_{OUT}	4.5 V ≤ AV_{DD} ≤ 5.5 V	±10			mA
		2.7 V ≤ AV_{DD} ≤ 5.5 V	±5			mA
Input-referred offset voltage	V_{OFF}	T_A = 25°C without trimming I_L = 0 mA, V_{COM} = 1.0 V		±1	±4	mV
		T_A = 25°C with trimming I_L = 0 mA, V_{COM} = 1.0 V			±0.35	mV
Temperature coefficient for inputreferred offset voltage	V_{OTC}	I_L = 0 mA		(±2)	(±8)	μV/°C
Slew rate	SR1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(0.1)		V/μs
	SR2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(0.8)		V/μs
Gain bandwidth	GBW1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(350)		kHz
	GBW2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(1.8)		MHz
Phase margin	θM1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(70)		deg
	θM2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(60)		deg
Settling time	tset1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(20)		μs
	tset2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(10)		μs
Peak-to-peak voltage noise	Enb	0.1 to 10 Hz Normal mode C_L = 50 pF, R_L = 10 kΩ		(2.0)		μVrms
Input-referred noise	En	f = 1 kHz, Normal mode C_L = 50 pF, R_L = 10 kΩ		(70)		nV/√Hz
Common mode rejection ratio	CMRR	f = 1 kHz, C_L = 50 pF, R_L = 10 kΩ		(70)		dB
Power supply rejection ratio	PSRR	2.7 V ≤ AV_{DD} ≤ 5.5 V f = 1 kHz, C_L = 50 pF, R_L = 10 kΩ		(62)		dB

(Remarks are listed on the next page.)

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Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The TYP. conditions are the conditions when TA = 25°C and AVDD = 5.0 V.
Remark 3. Unless otherwise specified, offset trimming has proceeded.
Remark 4. Unless otherwise specified, values are for operation in normal mode.

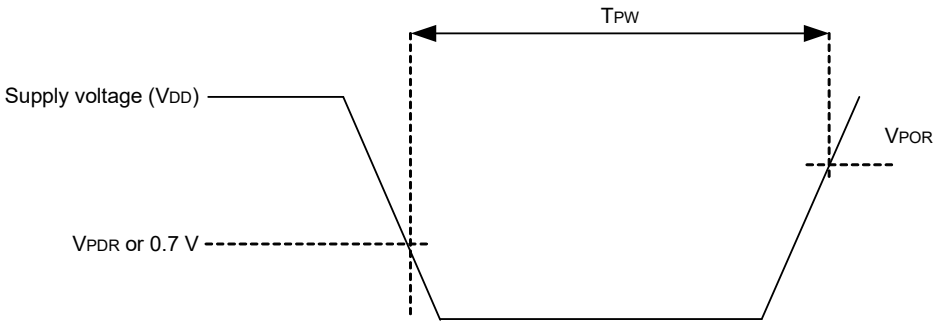
2.6.7 POR characteristics

(TA = -40 to +105°C, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	VPOR	Voltage threshold on VDD rising	1.48	1.56	1.62	V
	VPDR	Voltage threshold on VDD falling Note 1	1.47	1.55	1.61	V
Minimum pulse width Note 2	TPW		300			µs

Note 1. However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 2.4 AC Characteristics.

Note 2. Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



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2.6.8 LVD characteristics

(1) LVD detection voltage in reset mode and interrupt mode

(T_A = -40 to +105°C, $V_{PDR} \le AV_{DD} = V_{DD} \le$ 5.5 V, $AV_{SS} = V_{SS}$ = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Voltage detection threshold	Supply voltage level	V_{LVD0}	Rising edge	4.62	4.74	4.84	V
			Falling edge	4.52	4.64	4.74	V
		V_{LVD1}	Rising edge	4.50	4.62	4.72	V
			Falling edge	4.40	4.52	4.62	V
		V_{LVD2}	Rising edge	4.30	4.42	4.51	V
			Falling edge	4.21	4.32	4.41	V
		V_{LVD3}	Rising edge	3.13	3.22	3.29	V
			Falling edge	3.07	3.15	3.22	V
		V_{LVD4}	Rising edge	2.95	3.02	3.09	V
			Falling edge	2.89	2.96	3.02	V
		V_{LVD5}	Rising edge	2.74	2.81	2.87	V
			Falling edge	2.68	2.75	2.81	V
		V_{LVD6}	Rising edge	2.55	2.61	2.67	V
			Falling edge	2.49	2.55	2.61	V
Minimum pulse width		t_{LW}		300			µs
Detection delay time						300	µs

(2) LVD detection voltage in interrupt & reset mode

(T_A = -40 to +105°C, $V_{PDR} \le AV_{DD} = V_{DD} \le$ 5.5 V, $AV_{SS} = V_{SS}$ = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Voltage detection threshold	V_{LVDD6}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 0, 0, falling reset voltage		2.49	2.55	2.61	V
	V_{LVDD4}	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.95	3.02	3.09	V
			Falling interrupt voltage	2.89	2.96	3.02	V
	V_{LVDD3}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.13	3.22	3.29	V
			Falling interrupt voltage	3.07	3.15	3.22	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 0, 1, falling reset voltage		2.68	2.75	2.81	V
	V_{LVDD2}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.30	4.42	4.51	V
			Falling interrupt voltage	4.21	4.32	4.41	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 1, 0, falling reset voltage		2.68	2.75	2.81	V
	V_{LVDD1}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.50	4.62	4.72	V
			Falling interrupt voltage	4.40	4.52	4.62	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 1, 1, falling reset voltage		2.68	2.75	2.81	V
	V_{LVDD3}	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	3.13	3.22	3.29	V
			Falling interrupt voltage	3.07	3.15	3.22	V
	V_{LVDD0}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.62	4.74	4.84	V
			Falling interrupt voltage	4.52	4.64	4.74	V

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2.6.9 Power supply voltage rising slope characteristics

(T_A = -40 to +105°C, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S_{VDD}				50	V/ms

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until V_{DD} reaches the operating voltage range shown in 2.4 AC Characteristics.

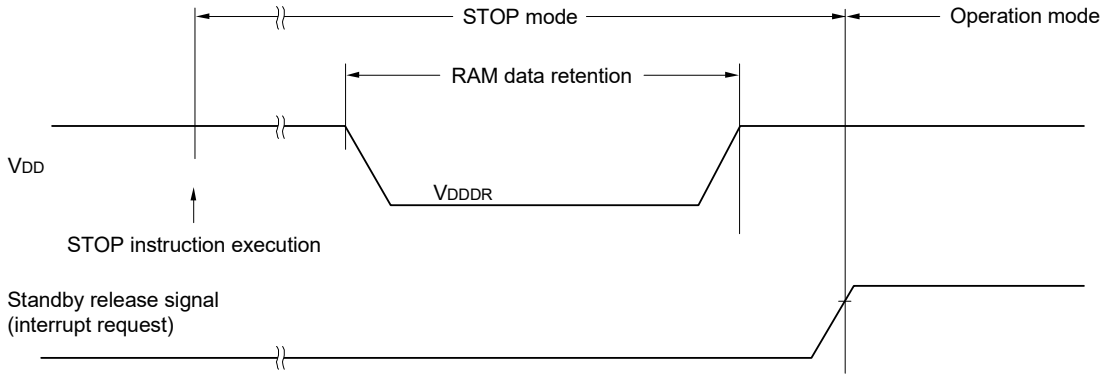
2.7 RAM Data Retention Characteristics

(T_A = -40 to +105°C, V_{SS} = 0 V))

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	V_{DDDR}		1.47 Notes 1, 2		5.5	V

Note 1. The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.

Note 2. Enter STOP mode before the supply voltage falls below the recommended operating voltage.



2.8 Flash Memory Programming Characteristics

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	f_{CLK}	2.4 V ≤ V_{DD} ≤ 5.5 V	1		32	MHz
Number of code flash rewrites Notes 1, 2, 3	C_{erwr}	Retained for 20 years T_A = 85°C Note 4	1,000			Times
Number of data flash rewrites Notes 1, 2, 3		Retained for 1 year T_A = 25°C Note 4		1,000,000		
		Retained for 5 years T_A = 85°C Note 4	100,000			
		Retained for 20 years T_A = 85°C Note 4	10,000			

Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

Note 2. When using flash memory programmer and Renesas Electronics self-programming library

Note 3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

Note 4. This temperature is the average value at which data are retained.

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2.9 Dedicated Flash Memory Programmer Communication (UART)

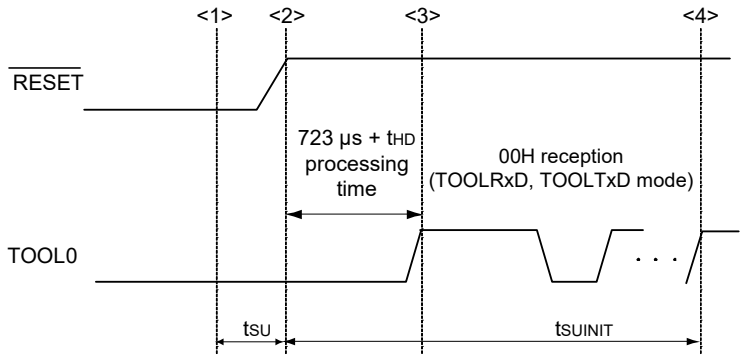
(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

2.10 Timing for Switching Flash Memory Programming Modes

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	t_{SUINIT}	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	t_{SU}	POR and LVD reset must end before the external reset ends.	10			µs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	t_{HD}	POR and LVD reset must end before the external reset ends.	1			ms



<1> The low level is input to the TOOL0 pin.
<2> The external reset ends (POR and LVD reset must end before the external reset ends).
<3> The TOOL0 pin is set to the high level.
<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUINIT}: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.
t_{SU}: How long from when the TOOL0 pin is placed at the low level until a pin reset ends
t_{HD}: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

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3. ELECTRICAL SPECIFICATIONS (M: T_A = -40 to +125°C)

This chapter describes the electrical specifications for the products “M: Industrial applications (T_A = -40 to +125°C)”.

Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

Caution 2. The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Alternate functions other than AFE in the RL78/I1E User's Manual.

Caution 3. Please contact Renesas Electronics sales office for derating of operation under T_A = +85 to +125°C. Derating is the systematic reduction of load for the sake of improved reliability.

Remark The electrical characteristics of the products M: Industrial applications (T_A = -40 to +125°C) are different from those of the products “G: Industrial applications”. For details, refer to **3.1** to **3.10**.

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3.1 Absolute Maximum Ratings

Absolute Maximum Ratings **(1/2)**

Parameter	Symbol	Conditions		Ratings	Unit
Supply voltage	V_{DD}			-0.5 to +6.5	V
	AV_{DD}	AV_{DD} = V_{DD}		-0.5 to +6.5	V
	AV_{SS}	AV_{SS} = V_{SS}		-0.5 to +0.3	V
REGC pin input voltage	V_{IREGC}	REGC		-0.3 to +2.8 and -0.3 to V_{DD} + 0.3 Note 1	V
REGA pin input voltage	V_{IREGA}	REGA		-0.3 to +2.8 and -0.3 to AV_{DD} + 0.3 Note 2	V
Input voltage	V_{I1}	P10 to P15, P40, P121, P122, P137, EXCLK, $\overline{\text{RESET}}$		-0.3 to V_{DD} +0.3 Note 3	V
Alternate-function pin input voltage	V_{I2}	P16, P17, P41, P42 (36-pin products only)	Digital input voltage	-0.3 to V_{DD} + 0.3 Note 3	V
			Analog input voltage	-0.3 to AV_{DD} + 0.3 Note 3	V
Analog input voltage	V_{IA}	PGA0P to PGA3P, PGA0N to PGA3N, ANI0 to ANI9, ANX0 to ANX5		-0.3 to AV_{DD} + 0.3 Note 3	V
Output voltage	V_{O1}	P10 to P15, P40		-0.3 to V_{DD} + 0.3 Note 3	V
Alternate-function pin output voltage	V_{O2}	P16, P17, P41, P42 (36-pin products only)	Digital output voltage	-0.3 to V_{DD} + 0.3 Note 3	V
			Analog output voltage	-0.3 to AV_{DD} + 0.3 Note 3	V
Analog output voltage	V_{OA}	SBIAS, AMP0O to AMP2O, ANX0 to ANX5		-0.3 to AV_{DD} + 0.3 Note 3	V

Note 1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

Note 2. Connect the REGA pin to AV_{SS} via a capacitor (0.22 μF). This value regulates the absolute maximum rating of the REGA pin. Do not use this pin with voltage applied to it.

Note 3. Must be 6.5 V or lower.

Caution **Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.**

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{SS} is used as the reference voltage.

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Absolute Maximum Ratings **(2/2)**

Parameter	Symbol	Conditions		Ratings	Unit
Output current, high	I_{OH1}	Per pin	P10 to P17, P40 to P42	-40	mA
		Total of all pins	P10 to P17, P41, P42 Note	-100	mA
Analog output current, high	I_{OHA}	Per pin	AMP0O to AMP2O	-12	mA
			ANX0 to ANX5	-0.12	mA
		Total of all pins	AMP0O to AMP2O, ANX0 to ANX5	-18	mA
Output current, low	I_{OL1}	Per pin	P10 to P17, P40 to P42	40	mA
		Total of all pins	P10 to P17, P41, P42 Note	100	mA
Analog output current, low	I_{OLA}	Per pin	AMP0O to AMP2O	12	mA
			ANX0 to ANX5	0.12	mA
		Total of all pins	AMP0O to AMP2O, ANX0 to ANX5	18	mA
Operating ambient temperature	T_A	In normal operation mode		-40 to +125	°C
		In flash memory programming mode			
Storage temperature	T_{stg}			-65 to +150	°C

Note This indicates the total current value when P16, P17, P41, and P42 are used as digital input pins.

Caution **Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.**

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
Remark 2. V_{SS} is used as the reference voltage.

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3.2 Oscillator Characteristics

3.2.1 X1 characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (f_X) Note	Ceramic resonator/ crystal resonator	2.7 V ≤ V_{DD} ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ V_{DD} < 2.7 V	1.0		16.0	

Note Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time.
Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution **Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.**

Remark When using the X1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/I1E User's Manual..

3.2.2 On-chip oscillator characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency Notes 1, 2	f_{IH}	2.7 V ≤ V_{DD} ≤ 5.5 V	1		24	MHz
		2.4 V ≤ V_{DD} < 2.7 V	1		16	MHz
High-speed on-chip oscillator clock frequency accuracy		-40 to +105°C	-2.0		+2.0	%
		+105 to +125°C	-3.0		+3.0	%
Low-speed on-chip oscillator clock frequency	f_{IL}			15		kHz
Low-speed on-chip oscillator clock frequency accuracy			-15		+15	%

Note 1. High-speed on-chip oscillator frequency is selected with bits 0 to 3 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

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3.2.3 PLL characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
PLL output frequency Notes 1, 2, 3	f_{PLL}	f_{MX} = 8 MHz	DSFRDIV = 0	DSCM = 0		48		MHz
			DSFRDIV = 1	DSCM = 0		24		MHz
				DSCM = 1		32		MHz
		f_{MX} = 4 MHz	DSFRDIV = 0	DSCM = 0		24		MHz
				DSCM = 1		32		MHz
Lockup wait time		Time from when PLL output is enabled to when the phase is locked			40			µs
Interval wait time		Time from when the PLL stops operating to when the setting to start PLL operation is specified			4			µs
Setup wait time		Time required from when the PLL input clock stabilizes and the PLL setting is determined to when the PLL is activated			1			µs

Note 1. When using a PLL, input a clock of 4 MHz or 8 MHz to the PLL.

Note 2. Be sure to specify one of these settings when using a PLL.

Note 3. When using the PLL output as the CPU clock, f_{IH} is divided by 2, 4, or 8 according to the setting of the RDIV1 and RDIV0 bits.

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3.3 DC Characteristics

3.3.1 Pin characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/3)**

Item	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high Note 1	I_{OH1}	Per pin for P10 to P17 and P40 to P42 Note 2	4.0 V ≤ V_{DD} ≤ 5.5 V			-3.0 Note 3	mA
			2.4 V ≤ V_{DD} < 4.0 V			-1.0 Note 3	mA
		Total of P10 to P17, P41, and P42 Note 3 (When duty ≤ 70% Note 4)	4.0 V ≤ V_{DD} ≤ 5.5 V			-30.0	mA
			2.7 V ≤ V_{DD} < 4.0 V			-19.0	mA
			2.4 V ≤ V_{DD} < 2.7 V			-10.0	mA
Output current, low Note 1	I_{OL1}	Per pin for P10 to P17 and P40 to P42 Note 2	4.0 V ≤ V_{DD} ≤ 5.5 V			8.5 Note 3	mA
			2.7 V ≤ V_{DD} < 4.0 V			1.5 Note 3	mA
			2.4 V ≤ V_{DD} < 2.7 V			0.6 Note 3	mA
		Total of P10 to P17, P41, and P42 Note 2 (When duty ≤ 70% Note 4)	4.0 V ≤ V_{DD} ≤ 5.5 V			40.0	mA
			2.7 V ≤ V_{DD} < 4.0 V			35.0	mA
			2.4 V ≤ V_{DD} < 2.7 V			20.0	mA

Note 1. Value of current at which the device operation is guaranteed even if the current flows from the V_{DD} pin to an output pin.

Note 2. This indicates the total current value when P16, P17, P41, and P42 are used as digital I/O ports. When using these pins as analog function (AFE) pins, refer to **3.1 Absolute Maximum Ratings**.

Note 3. Do not exceed the total current value.

Note 4. Specification under conditions where the duty factor ≤ 70%.
The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I_{OH} × 0.7)/(n × 0.01)

  Example: n = 80% when I_{OH} = -10.0 mA
  Total output current of pins = (-10.0 × 0.7)/(80 × 0.01) ≈ -8.7 mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.
A current higher than the absolute maximum rating must not flow into one pin.

Caution **P10 to P15 do not output high level in N-ch open-drain mode.**

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/3)**

Item	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input voltage, high	V_{IH1}	P10 to P17 and P40 to P42	Normal input buffer	0.8 V_{DD}		V_{DD}	V
	V_{IH2}	P11, P12, P14, P15	TTL input buffer, 4.0 V ≤ V_{DD} ≤ 5.5 V	2.2		V_{DD}	V
			TTL input buffer, 3.3 V ≤ V_{DD} < 4.0 V	2.0		V_{DD}	V
			TTL input buffer, 2.4 V ≤ V_{DD} < 3.3 V	1.28		V_{DD}	V
	V_{IH3}	P121, P122, P137, EXCLK, $\overline{\text{RESET}}$		0.8 V_{DD}		V_{DD}	V
Input voltage, low	V_{IL1}	P10 to P17 and P40 to P42	Normal input buffer	0		0.2 V_{DD}	V
	V_{IL2}	P11, P12, P14, P15	TTL input buffer, 4.0 V ≤ V_{DD} ≤ 5.5 V	0		0.8	V
			TTL input buffer, 3.3 V ≤ V_{DD} < 4.0 V	0		0.5	V
			TTL input buffer, 2.4 V ≤ V_{DD} < 3.3 V	0		0.32	V
	V_{IL3}	P121, P122, P137, EXCLK, $\overline{\text{RESET}}$		0		0.2 V_{DD}	V
Output voltage, high	V_{OH1}	P10 to P17 and P40 to P42	4.0 V ≤ V_{DD} ≤ 5.5 V, I_{OH1} = -3.0 mA	V_{DD} - 0.7			V
			2.4 V ≤ V_{DD} ≤ 5.5 V, I_{OH1} = -1.0 mA	V_{DD} - 0.5			V
Output voltage, low	V_{OL1}	P10 to P17 and P40 to P42	4.0 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 8.5 mA			0.7	V
			2.7 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 1.5 mA			0.5	V
			2.4 V ≤ V_{DD} ≤ 5.5 V, I_{OL1} = 0.6 mA			0.4	V

Caution The maximum V_{IH} value on P10 to P15 is V_{DD}, even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(3/3)**

Item	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Input leakage current, high	I_{LIH1}	P10 to P17, and P40 to P42	V_I = V_{DD}				1	μA
	I_{LIH2}	P137, $\overline{\text{RESET}}$	V_I = V_{DD}				1	μA
	I_{LIH3}	P121, P122 (X1, X2, EXCLK)	V_I = V_{DD}	In input port mode or when using external clock input			1	μA
				When a resonator is connected			10	μA
Input leakage current, low	I_{LIL1}	P10 to P17, and P40 to P42	V_I = V_{SS}				-1	μA
	I_{LIL2}	P137, $\overline{\text{RESET}}$	V_I = V_{SS}				-1	μA
	I_{LIL3}	P121, P122 (X1, X2, EXCLK)	V_I = V_{SS}	In input port mode or when using external clock input			-1	μA
				When a resonator is connected			-10	μA
On-chip pull-up resistance	R_U	P10 to P15, P40	V_I = V_{SS}, in input port mode		10	20	100	kΩ

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

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3.3.2 Supply current characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current Note 1	I_{DD1}	Operating mode Note 2	f_{HOCO} = 24 MHz, f_{MAIN} = 24 MHz Note 3	Basic operation	V_{DD} = 5.0 V		1.7		mA
					V_{DD} = 3.0 V		1.7		
			f_{HOCO} = 24 MHz, f_{MAIN} = 24 MHz Note 3	Normal operation	V_{DD} = 5.0 V		3.8	7.6	mA
					V_{DD} = 3.0 V		3.8	7.6	
			f_{HOCO} = 16 MHz, f_{MAIN} = 16 MHz Note 3	Normal operation	V_{DD} = 5.0 V		2.8	5.6	
					V_{DD} = 3.0 V		2.8	5.6	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 4, V_{DD} = 5.0 V	Normal operation	Square wave input		3.3	6.5	mA
					Resonator connection		3.5	6.6	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 4, V_{DD} = 3.0 V	Normal operation	Square wave input		3.3	6.5	
					Resonator connection		3.5	6.6	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 4, V_{DD} = 5.0 V	Normal operation	Square wave input		2.0	3.9	
					Resonator connection		2.1	4.0	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 4, V_{DD} = 3.0 V	Normal operation	Square wave input		2.0	3.9	
					Resonator connection		2.1	4.0	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 5, V_{DD} = 5.0 V	Normal operation	Square wave input		5.1	10.4	mA
					Resonator connection		5.2	10.5	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 5, V_{DD} = 3.0 V	Normal operation	Square wave input		5.1	10.4	
					Resonator connection		5.2	10.5	

Note 1. Total current flowing into V_{DD}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD} or V_{SS}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

Note 2. The relationship between the operation voltage range and the CPU operating frequency is as below.
2.7 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 24 MHz
2.4 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 16 MHz

Note 3. When the high-speed system clock is stopped

Note 4. When the high-speed on-chip oscillator and the PLL are stopped

Note 5. When the high-speed on-chip oscillator is stopped and the PLL is operating

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{HOCO}: High-speed on-chip oscillator clock frequency

Remark 3. f_{MAIN}: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is T_A = 25°C

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(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/2)**

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Supply current Note 1	I_{DD2} Note 2	HALT mode Note 3	f_{HOCO} = 24 MHz, f_{MAIN} = 24 MHz Note 4	V_{DD} = 5.0 V		0.44	3.42	mA
				V_{DD} = 3.0 V		0.44	3.42	
			f_{HOCO} = 16 MHz, f_{MAIN} = 16 MHz Note 4	V_{DD} = 5.0 V		0.40	2.50	
				V_{DD} = 3.0 V		0.40	2.50	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 5, V_{DD} = 5.0 V	Square wave input		0.28	2.94	mA
				Resonator connection		0.49	3.08	
			f_{MX} = 20 MHz, f_{MAIN} = 20 MHz Note 5, V_{DD} = 3.0 V	Square wave input		0.28	2.94	
				Resonator connection		0.49	3.08	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 5, V_{DD} = 5.0 V	Square wave input		0.19	1.54	
				Resonator connection		0.30	1.63	
			f_{MX} = 10 MHz, f_{MAIN} = 10 MHz Note 5, V_{DD} = 3.0 V	Square wave input		0.19	1.54	
				Resonator connection		0.30	1.63	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 6, V_{DD} = 5.0 V	Square wave input		0.76	3.92	mA
				Resonator connection		0.86	4.04	
			f_{MX} = 8 MHz, f_{MAIN} = 24 MHz Note 6, V_{DD} = 3.0 V	Square wave input		0.76	3.92	
				Resonator connection		0.86	4.04	
	I_{DD3} Note 7	STOP mode	T_A = -40°C			0.38	1.14	µA
			T_A = +25°C			0.50	1.14	
			T_A = +50°C			0.66	4.52	
			T_A = +70°C			1.04	7.98	
			T_A = +85°C			2.92	16.0	
			T_A = +105°C			11.0	100.0	
			T_A = +125°C			22.0	200.0	

Note 1. Total current flowing into V_{DD}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD} or V_{SS}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during writing to the data flash.

Note 2. During HALT instruction execution from flash memory

Note 3. The relationship between the operation voltage range and the CPU operating frequency is as below.
2.7 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 24 MHz
2.4 V ≤ V_{DD} ≤ 5.5 V @ 1 MHz to 16 MHz

Note 4. When the high-speed system clock is stopped

Note 5. When the high-speed on-chip oscillator and the PLL are stopped

Note 6. When high-speed on-chip oscillator is stopped and the PLL is operating

Note 7. The MAX. value includes the leakage current in STOP mode.

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{HOCO}: High-speed on-chip oscillator clock frequency

Remark 3. f_{MAIN}: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is T_A = 25°C, except the operation in STOP mode.

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• Peripheral functions

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I_{FIL} Note 1				0.20		μA
RTC operating current	I_{RTC} Notes 1, 2, 3	f_{MX} = 4 MHz, RTCCL = 00H (f_{MX}/122)			22		μA
Interval timer operating current	I_{IT} Notes 1, 2, 4	f_{MX} = 4 MHz, RTCCL = 00H (f_{MX}/122)			22		μA
Watchdog timer operating current	I_{WDT} Notes 1, 5, 6	f_{IL} = 15 kHz			0.22		μA
LVD operating current	I_{LVD} Notes 1, 7				0.08		μA
Self-programming operating current	I_{FSP} Notes 1, 8				2.00	12.20	mA
BGO operating current	I_{BGO} Notes 1, 9				2.00	12.20	mA
SNOOZE operating current	I_{SNOZ} Note 1	A/D converter operation Notes 10,	The mode is performed		0.50	1.10	mA
			During A/D conversion, AV_{DD} = V_{DD} = 3.0 V		1.20	2.04	
		Simplified SPI(CSI)/UART operation			0.70	1.54	
		DTC operation			3.10		

Note 1. Current flowing to V_{DD}

Note 2. When the high-speed on-chip oscillator is stopped

Note 3. Current flowing only to the real-time clock (RTC). The supply current of the RL78 microcontrollers is the sum of the values of either I_{DD1} or I_{DD2}, and I_{RTC}, when the real-time clock is operating in operation mode or HALT mode.

Note 4. Current flowing only to the interval timer. The supply current of the RL78 microcontrollers is the sum of the values of either I_{DD1} or I_{DD2}, and I_{IT}, when the interval timer is operating in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, also add I_{FIL}.

Note 5. When the high-speed on-chip oscillator and high-speed system clock are stopped.

Note 6. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{WDT} when the watchdog timer is operating.

Note 7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of I_{DD1}, I_{DD2} or I_{DD3} and I_{LVD} when the LVD circuit is operating.

Note 8. Current flowing during self-programming

Note 9. Current flowing during writing to the data flash

Note 10. The current flowing into the AV_{DD} is included.

Remark 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. f_{IL}: Low-speed on-chip oscillator clock frequency

Remark 3. The temperature condition for the TYP. value is T_A = 25°C

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• AFE functions

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
24-bit ΔΣ A/D converter operating current	I_{DSAD}	Normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS I_{OUT} = 0 mA		0.94	1.46	mA
		Low power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS I_{OUT} = 0 mA		0.60	0.91	mA
10-bit A/D converter operating current	I_{ADC}	During conversion at the highest speed Notes 1, 2 AV_{DD} = 5.0 V		1.30	1.70	mA
Configurable amplifier operating current	I_{AMP}	Normal mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier I_L = 0 mA Per channel		0.13	0.24	mA
		High-speed mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier I_L = 0 mA Per channel		0.30	0.45	mA
12-bit D/A converter operating current	I_{DAC}	When AV_{DD} and AV_{SS} are selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR and internal reference voltage (VREFDA)		0.61	0.97	mA

Note 1. Current flowing to AV_{DD}

Note 2. Current flowing only to the circuits that operate shown in the Conditions column.

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3.4 AC Characteristics

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

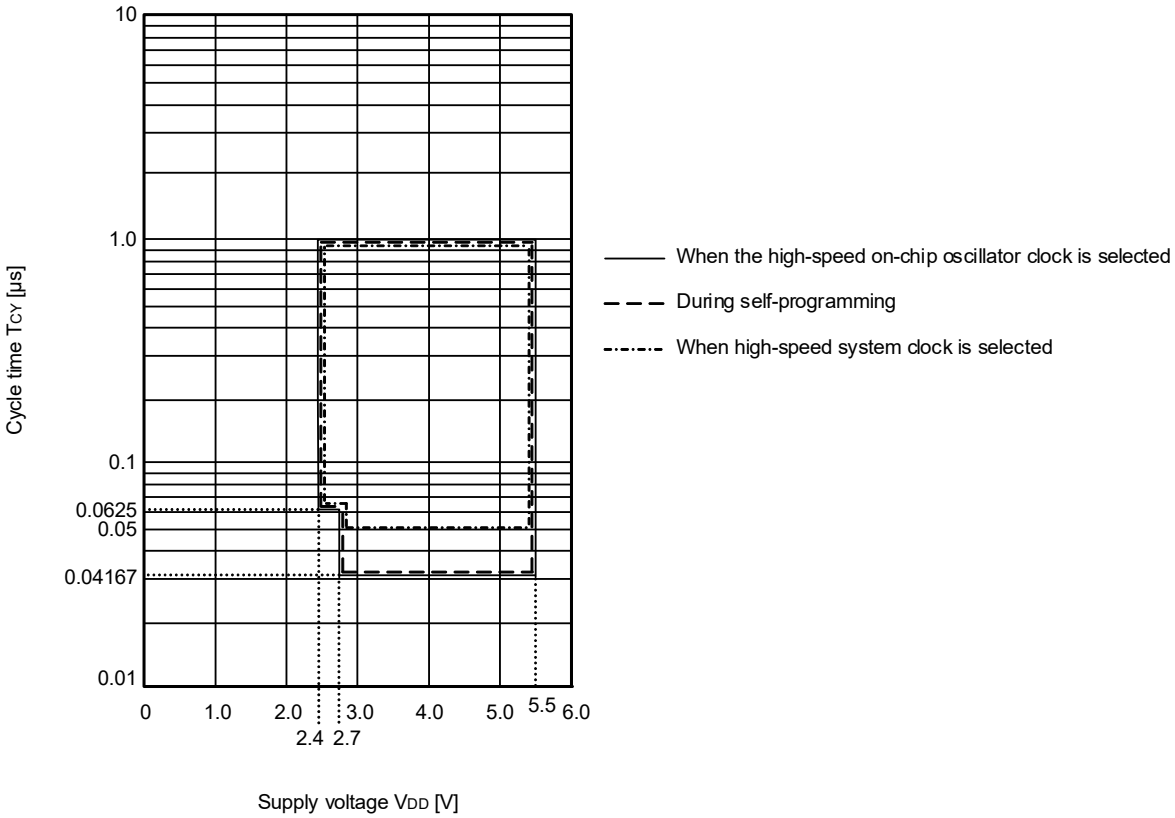
Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T_{CY}	Main system clock (f_{MAIN}) operation	2.7 V ≤ V_{DD} ≤ 5.5 V	0.04167		1	µs
			2.4 V ≤ V_{DD} < 2.7 V	0.0625		1	µs
		In the self-programming mode	2.7 V ≤ V_{DD} ≤ 5.5 V	0.04167		1	µs
			2.4 V ≤ V_{DD} < 2.7 V	0.0625		1	µs
External system clock frequency	f_{EX}	2.7 V ≤ V_{DD} ≤ 5.5 V		1.0		20.0	MHz
		2.4 V ≤ V_{DD} < 2.7 V		1.0		8.0	MHz
External system clock input high-level width, low-level width	t_{EXH}, t_{EXL}	2.7 V ≤ V_{DD} ≤ 5.5 V		24			ns
		2.4 V ≤ V_{DD} < 2.7 V		60			ns
TI00 to TI03, TI10, TI11 input high-level width, low-level width	t_{TIH}, t_{TIL}			1/f_{MCK} + 10			ns
Timer RJ input cycle	f_C	TRJIO0	2.7 V ≤ V_{DD} ≤ 5.5 V	100			ns
			2.4 V ≤ V_{DD} < 2.7 V	300			ns
Timer RJ input high-level width, low-level width	t_{TJIH}, t_{TJIL}	TRJIO0	2.7 V ≤ V_{DD} ≤ 5.5 V	40			ns
			2.4 V ≤ V_{DD} < 2.7 V	120			ns
Timer RG input high-level width, low-level width	t_{TGIH}, t_{TGIL}	TRGIOA, TRGIOB		2.5/f_{CLK}			ns
TO00 to TO03, TO10, TO11, TRJIO0, TRJO0, TRGIOA, TRGIOB output frequency	f_{TO}		4.0 V ≤ V_{DD} ≤ 5.5 V			12	MHz
			2.7 V ≤ V_{DD} ≤ 4.0 V			6	MHz
			2.4 V ≤ V_{DD} < 2.7 V			3	MHz
PCLBUZ0 output frequency	f_{PCL}		4.0 V ≤ V_{DD} ≤ 5.5 V			12	MHz
			2.7 V ≤ V_{DD} ≤ 4.0 V			6	MHz
			2.4 V ≤ V_{DD} < 2.7 V			3	MHz
Interrupt input high-level width, low-level width	t_{INTH}, t_{INTL}	INTP1 to INTP7		1			µs
$\overline{\text{RESET}}$ low-level width	t_{RSL}			10			µs

Remark f_{MCK}: Timer array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

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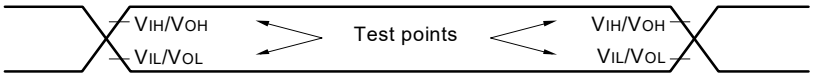
Minimum Instruction Execution Time During Main System Clock Operation

TCY vs VDD

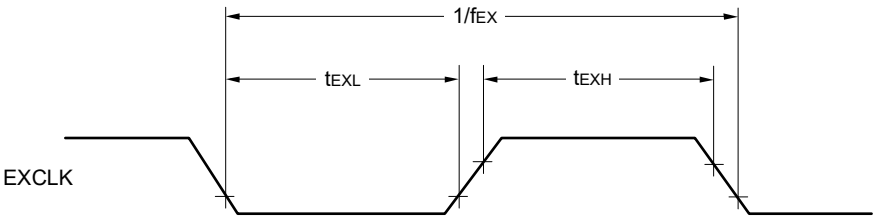


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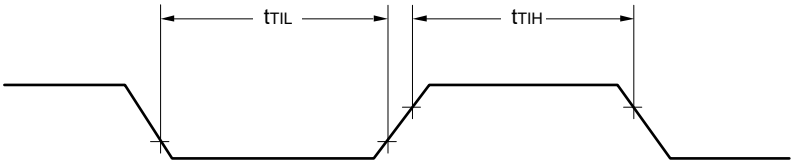
AC Timing Test Points



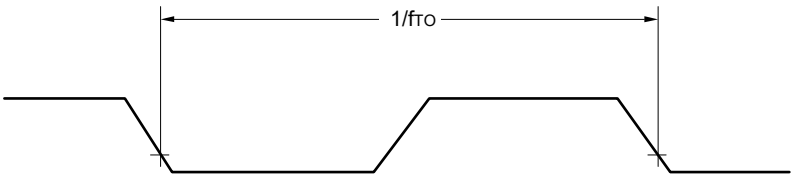
External System Clock Timing



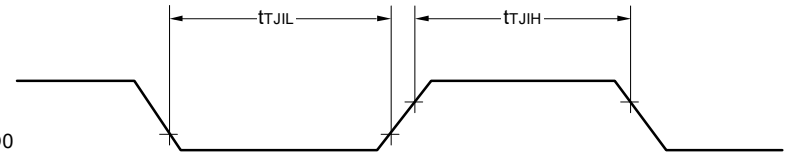
TI/TO Timing



TI00 to TI03, TI10, TI11

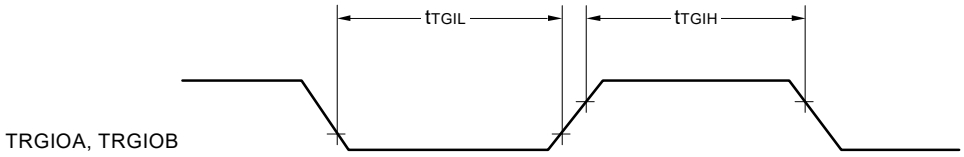


TO00 to TO03, TO10, TI11,
TRJIO0, TRJO0,
TRGIOA, TRGIOB

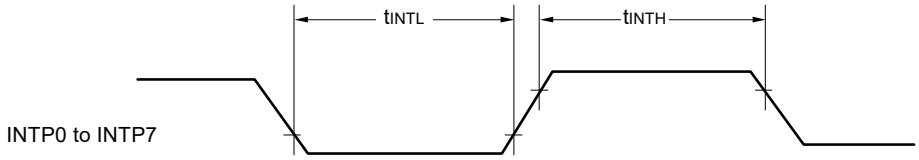


TRJIO0

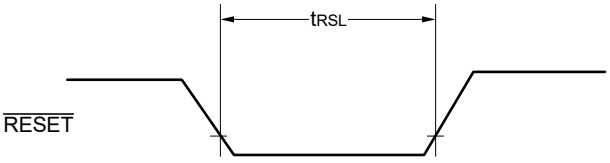
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Interrupt Request Input Timing



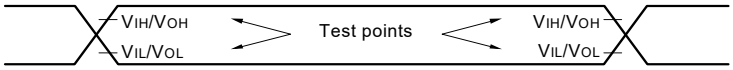
$\overline{\text{RESET}}$ Input Timing



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3.5 Peripheral Functions Characteristics

AC Timing Test Points



3.5.1 Serial array unit

(1) During communication at same potential (UART mode)

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

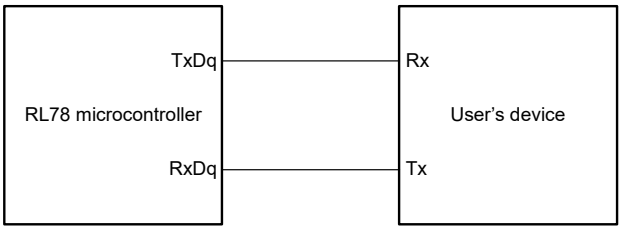
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate Note 1				fMCK/12	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 2		2.0	Mbps

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

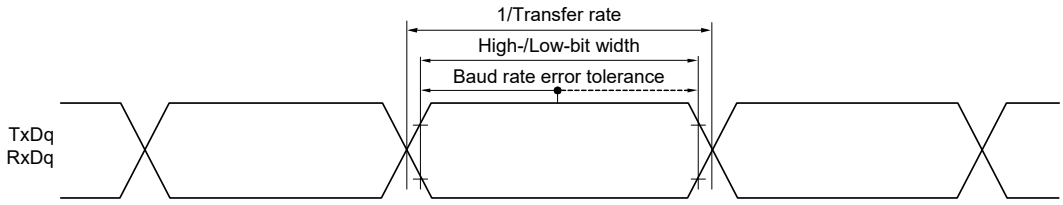
Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:
24 MHz (2.7 V ≤ VDD ≤ 5.5 V)
16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

UART mode connection diagram (during communication at same potential)



UART mode bit width (during communication at same potential) (reference)



Remark 1. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 2. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03))

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(2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t_{KCY1}	$t_{KCY1} \geq 4/f_{CLK}$	2.7 V ≤ V_{DD} ≤ 5.5 V	333		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	666		ns
SCKp high-/low-level width	t_{KH1}, t_{KL1}	4.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 24		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 36		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2 - 76		ns
SIp setup time (to SCKp↑) Note 1	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V		66		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		66		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		113		ns
SIp hold time (from SCKp↑) Note 1	t_{KSI1}			38		ns
Delay time from SCKp↓ to SOp output Note 2	t_{KSO1}	C = 30 pF Note 3			66.6	ns

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

Remark 2. f_{MCK}: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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(3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time Note 1	t_{KCY2}	4.0 V ≤ V_{DD} ≤ 5.5 V	20 MHz < f_{MCK}	16/f_{MCK}		ns
			f_{MCK} ≤ 20 MHz	12/f_{MCK}		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V	16 MHz < f_{MCK}	16/f_{MCK}		ns
			f_{MCK} ≤ 16 MHz	12/f_{MCK}		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		12/f_{MCK} and 1000		ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	4.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 14		ns
		2.7 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 16		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2 - 36		ns
SIp setup time (to SCKp↑) Note 2	t_{SIK2}	2.7 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 40		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 60		ns
SIp hold time (from SCKp↑) Note 2	t_{KSI2}			1/f_{MCK} + 62		ns
Delay time from SCKp↓ to SOp output Note 3	t_{KSO2}	C = 30 pF Note 4	2.7 V ≤ V_{DD} ≤ 5.5 V		2/f_{MCK} + 66	ns
			2.4 V ≤ V_{DD} ≤ 5.5 V		2/f_{MCK} + 113	ns
$\overline{SSI00}$ setup time	t_{SSIK}	DAPmn = 0	2.7 V ≤ V_{DD} ≤ 5.5 V	240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	400		ns
		DAPmn = 1	2.7 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 400		ns
$\overline{SSI00}$ hold time	t_{KSSI}	DAPmn = 0	2.7 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	1/f_{MCK} + 400		ns
		DAPmn = 1	2.7 V ≤ V_{DD} ≤ 5.5 V	240		ns
			2.4 V ≤ V_{DD} ≤ 5.5 V	400		ns

Note 1. The maximum transfer rate in the SNOOZE mode is 1 Mbps.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SOp output lines.

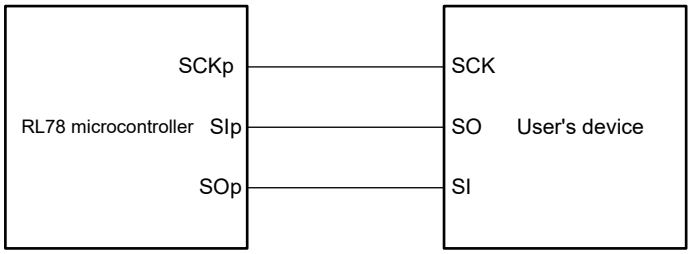
Caution Select the normal input buffer for the SIp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

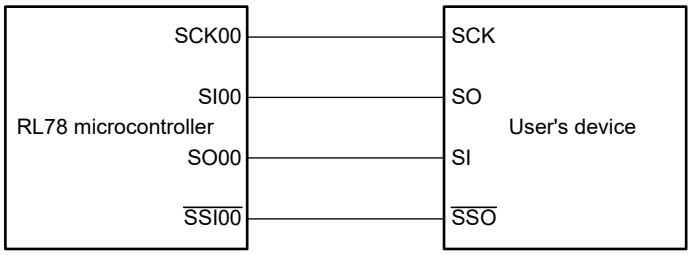
Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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Simplified SPI(CSI) mode connection diagram (during communication at same potential)



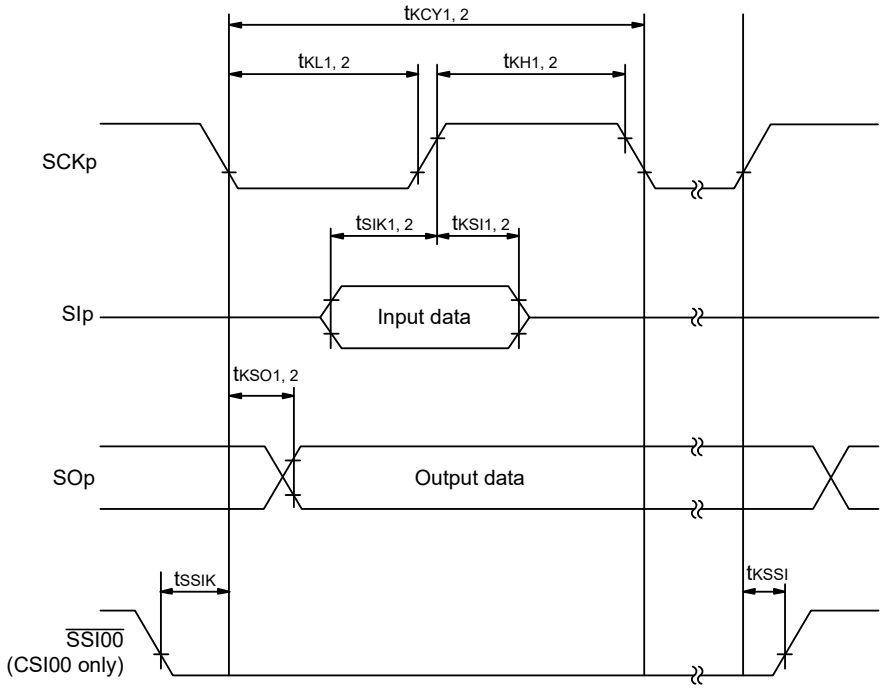
Simplified SPI(CSI) mode connection diagram (during communication at same potential)
(Slave Transmission of slave select input function (CSI00))



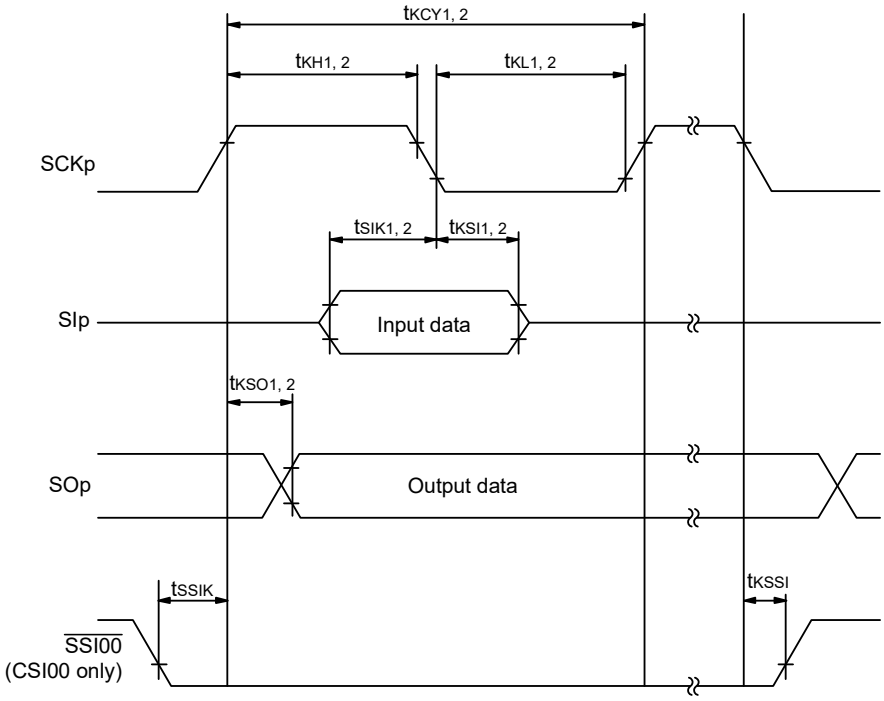
Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)
Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

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Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)
Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

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(4) During communication at same potential (simplified I²C mode)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f_{SCL}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ		100 Note 1	kHz
Hold time when SCLr = "L"	t_{LOW}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	4600		ns
Hold time when SCLr = "H"	t_{HIGH}	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	4600		ns
Data setup time (reception)	$t_{SU:DAT}$	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 220 Note 2		ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	1/f_{MCK} + 580 Note 2		ns
Data hold time (transmission)	$t_{HD:DAT}$	2.7 V ≤ V_{DD} ≤ 5.5 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		2.4 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	0	1420	ns

Note 1. The value must also be equal to or less than f_{MCK}/4.

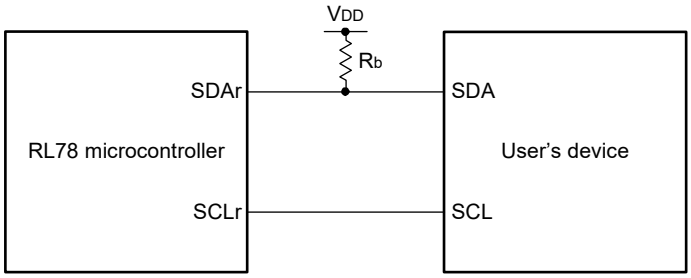
Note 2. Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

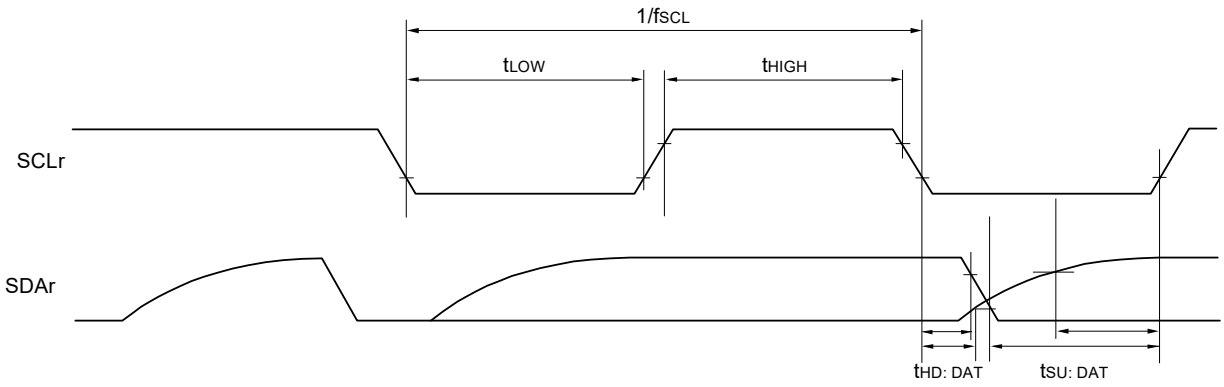
(Remarks are listed on the next page.)

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Simplified I²C mode connection diagram (during communication at same potential)



Simplified I²C mode serial transfer timing (during communication at same potential)



Remark 1. Rb [Ω]: Communication line (SDAr) pull-up resistance, Cb [F]: Communication line (SDAr, SCLr) load capacitance

Remark 2. r: IIC number (r = 00, 01), g: PIM number (g = 1), h: POM number (h = 1)

Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0, 1), mn = 00, 01)

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(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
Transfer rate		Reception	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.0	Mbps
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.0	Mbps
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		f_{MCK}/12 Note 1	bps
			Theoretical value of the maximum transfer rate f_{MCK} = f_{CLK} Note 2		2.0	Mbps

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (f_{CLK}) are:
24 MHz (2.7 V ≤ V_{DD} ≤ 5.5 V)
16 MHz (2.4 V ≤ V_{DD} ≤ 5.5 V)

Caution **Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.**

Remark 1. V_b [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01)

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(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/2)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		Note 1	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 1.4 kΩ, V_b = 2.7 V		2.0 Note 2	Mbps
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		Note 3	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 2.7 kΩ, V_b = 2.3 V		1.2 Note 4	Mbps
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		Note 5	bps
			Theoretical value of the maximum transfer rate C_b = 50 pF, R_b = 5.5 kΩ, V_b = 1.6 V		0.43 Note 6	Mbps

Note 1. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ V_{DD} ≤ 5.5 V and 2.7 V ≤ V_b ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 2. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

Note 3. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V_{DD} < 4.0 V and 2.3 V ≤ V_b ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 4. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

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Note 5. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.
Expression for calculating the transfer rate when 2.4 V ≤ V_{DD} < 3.3 V and 1.6 V ≤ V_b ≤ 2.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [\%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

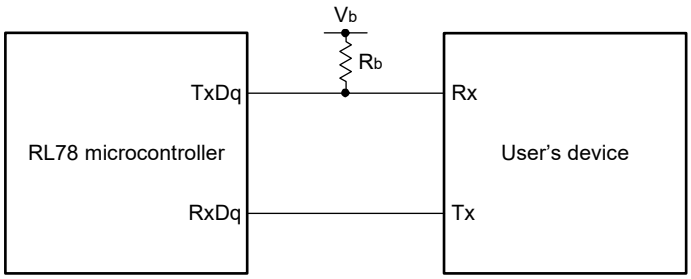
Note 6. This value as an example is calculated when the conditions described in the “Conditions” column are met.
Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

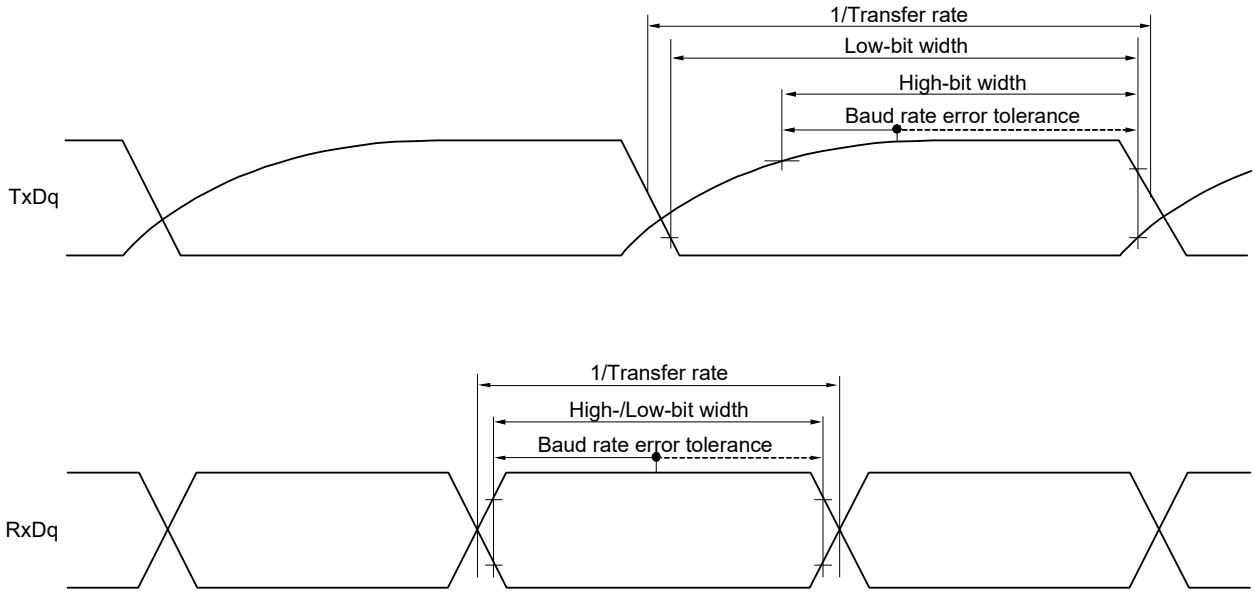
(Remarks are listed on the next page.)

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UART mode connection diagram (during communication at different potential)



UART mode bit width (during communication at different potential) (reference)



Remark 1. Rb [Ω]: Communication line (TxDq) pull-up resistance,
Cb [F]: Communication line (TxDq) load capacitance, Vb [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/3)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t_{KCY1}	$t_{KCY1} \geq 4/f_{CLK}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	600		ns
			2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	1000		ns
			2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	2300		ns
SCKp high-level width	t_{KH1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		t_{KCY1}/2 - 150		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		t_{KCY1}/2 - 340		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		t_{KCY1}/2 - 916		ns
SCKp low-level width	t_{KL1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		t_{KCY1}/2 - 24		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		t_{KCY1}/2 - 36		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		t_{KCY1}/2 - 100		ns

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) (2/3)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SIp setup time (to SCKp↑) Note	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	162		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	354		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	958		ns
SIp hold time (from SCKp↑) Note	t_{KSI1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	38		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	38		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	38		ns
Delay time from SCKp↓ to SOp output Note	t_{KSO1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		200	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		390	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		966	ns

Note When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

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(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) (3/3)

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SIp setup time (to SCKp↓) Note	t_{SIK1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	88		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	88		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	220		ns
SIp hold time (from SCKp↓) Note	t_{KSI1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ	38		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ	38		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ	38		ns
Delay time from SCKp↑ to SOp output Note	t_{KSO1}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ		50	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ		50	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ		50	ns

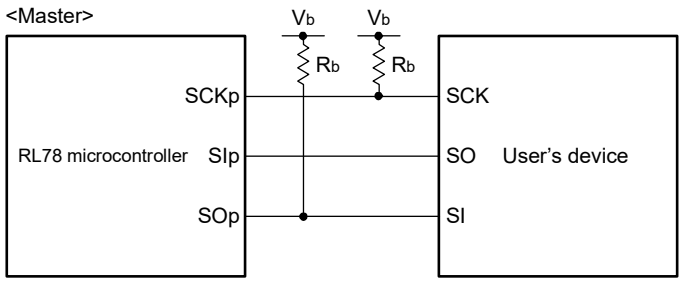
Note When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

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Simplified SPI (CSI) mode connection diagram (during communication at different potential



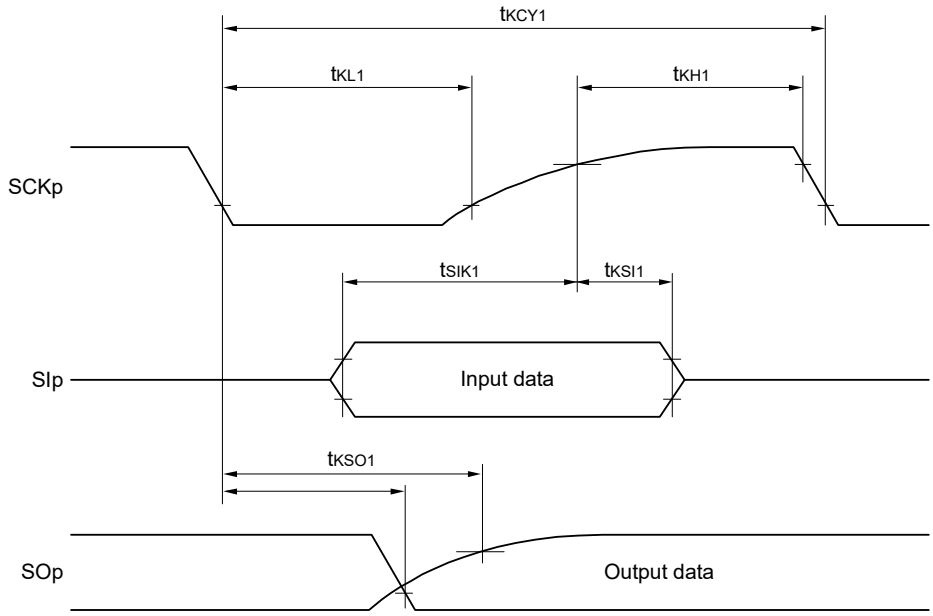
Remark 1. Rb [Ω]: Communication line (SCKp, SOp) pull-up resistance, Cb [F]: Communication line (SCKp, SOp) load capacitance, Vb [V]: Communication line voltage

Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

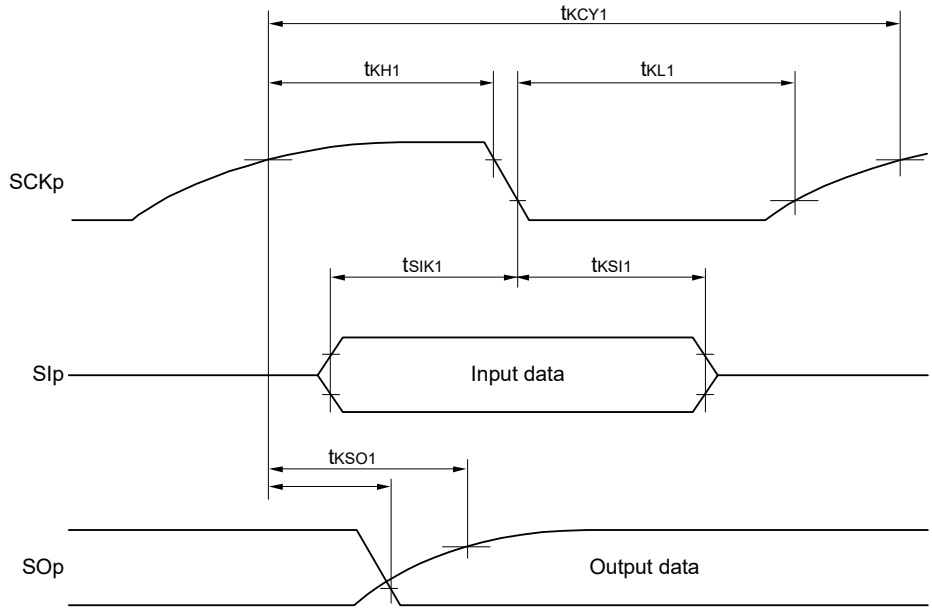
Remark 3. fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

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Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

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(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time Note 1	t_{KCY2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V	20 MHz < f_{MCK} ≤ 24 MHz	24/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 20 MHz	20/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	16/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	12/f_{MCK}		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V	20 MHz < f_{MCK} ≤ 24 MHz	32/f_{MCK}		ns
			16 MHz < f_{MCK} ≤ 20 MHz	28/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 16 MHz	24/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	16/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	12/f_{MCK}		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V	20 MHz < f_{MCK} ≤ 24 MHz	72/f_{MCK}		ns
			16 MHz < f_{MCK} ≤ 20 MHz	64/f_{MCK}		ns
			8 MHz < f_{MCK} ≤ 16 MHz	52/f_{MCK}		ns
			4 MHz < f_{MCK} ≤ 8 MHz	32/f_{MCK}		ns
			f_{MCK} ≤ 4 MHz	20/f_{MCK}		ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		t_{KCY2}/2 - 24		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		t_{KCY2}/2 - 36		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		t_{KCY2}/2 - 100		ns
SIp setup time (to SCKp↑) Note 2	t_{SIK2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V		1/f_{MCK} + 40		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V		1/f_{MCK} + 40		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V		1/f_{MCK} + 60		ns
SIp hold time (from SCKp↑) Note 2	t_{KSI2}			1/f_{MCK} + 62		ns
Delay time from SCKp↓ to SOp output Note 3	t_{KSO2}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 30 pF, R_b = 1.4 kΩ			2/f_{MCK} + 240	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 30 pF, R_b = 2.7 kΩ			2/f_{MCK} + 428	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 30 pF, R_b = 5.5 kΩ			2/f_{MCK} + 1146	ns

(Notes, Cautions, and Remarks are listed on the next page.)

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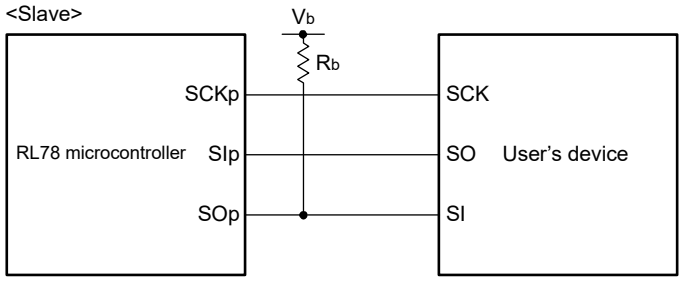
Note 1. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Caution Select the TTL input buffer for the SIp and SCKp pins, and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

Simplified SPI(CSI) mode connection diagram (during communication at different potential)



Remark 1. R_b [Ω]: Communication line (SOp) pull-up resistance, C_b [F]: Communication line (SOp) load capacitance, V_b [V]: Communication line voltage

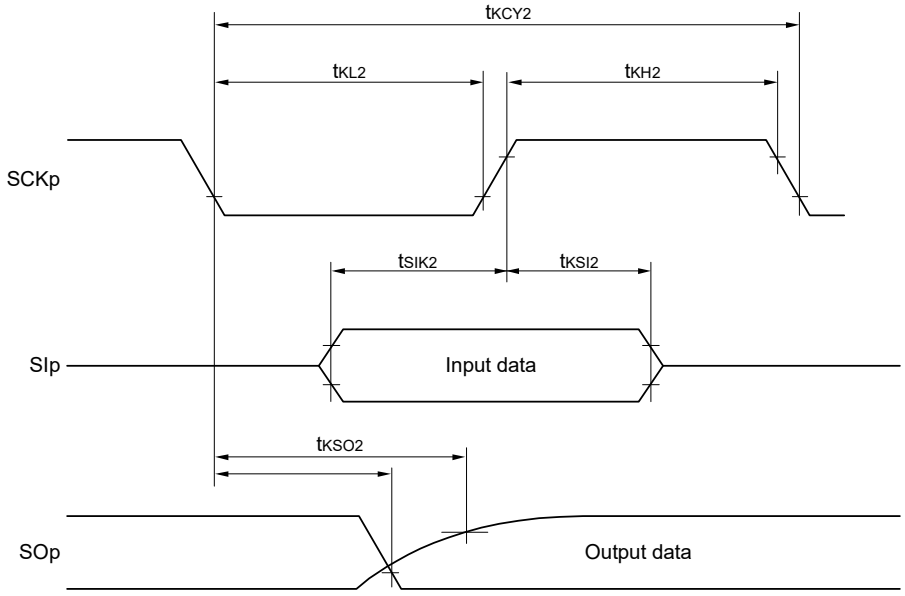
Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0 , 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))

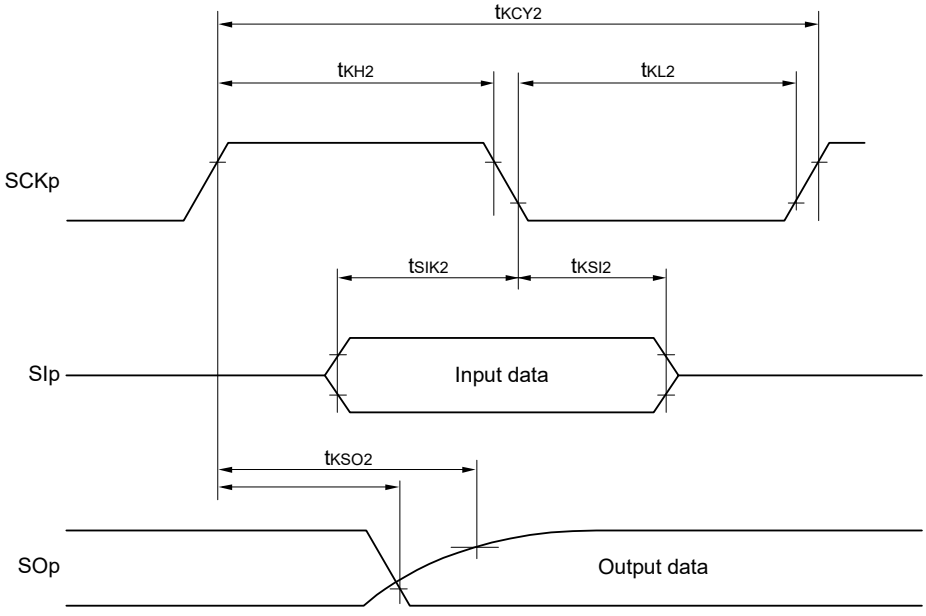
Remark 4. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

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Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

Remark 2. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

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(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f_{SCL}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ		100 Note 1	kHz
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ		100 Note 1	kHz
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ		100 Note 1	kHz
Hold time when SCLr = “L”	t_{LOW}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	4600		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	4600		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	4600		ns
Hold time when SCLr = “H”	t_{HIGH}	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	620		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	500		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	2700		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	2400		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	1830		ns

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(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I^2C mode)

(T_A = -40 to +125°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V) **(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Data setup time (reception)	$t_{SU:DAT}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 340 Note 1		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	1/f_{MCK} + 340 Note 2		ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	1/f_{MCK} + 760 Note 2		ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	1/f_{MCK} + 760 Note 2		ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	1/f_{MCK} + 570 Note 2		ns
Data hold time (transmission)	$t_{HD:DAT}$	4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	0	770	ns
		4.0 V ≤ V_{DD} ≤ 5.5 V, 2.7 V ≤ V_b ≤ 4.0 V, C_b = 100 pF, R_b = 2.8 kΩ	0	1420	ns
		2.7 V ≤ V_{DD} < 4.0 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	0	1420	ns
		2.4 V ≤ V_{DD} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	0	1215	ns

Note 1. The value must also be equal to or less than f_{MCK}/4.

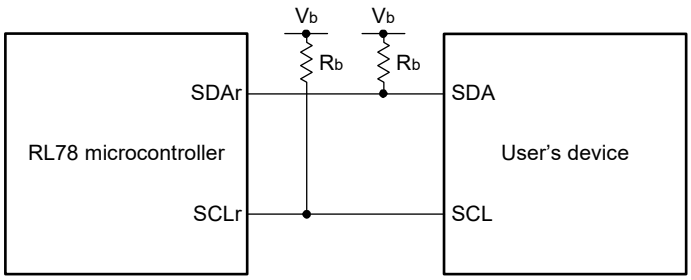
Note 2. Set the f_{MCK} value to keep the hold time of SCLr = “L” and SCLr = “H”.

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

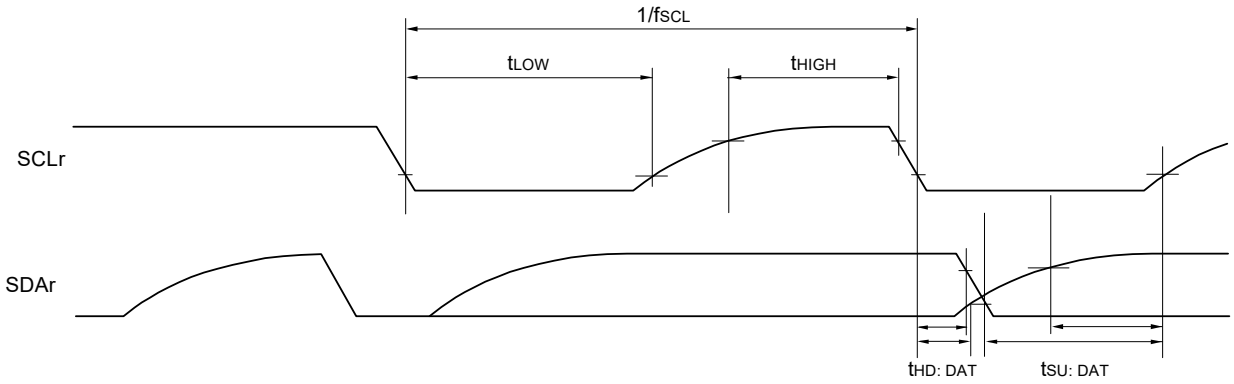
(Remarks are listed on the next page.)

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Simplified I²C mode connection diagram (during communication at different potential)



Simplified I²C mode serial transfer timing (during communication at different potential)



Remark 1. R_b [Ω]: Communication line (SDAr, SCLr) pull-up resistance, C_b [F]: Communication line (SDAr, SCLr) load capacitance, V_b [V]: Communication line voltage

Remark 2. r: IIC number (r = 00, 01), g: PIM, POM number (g = 1)

Remark 3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0), mn = 00, 01)

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3.6 Analog Characteristics

3.6.1 Programmable gain instrumentation amplifier and 24-bit ΔΣ A/D converter

(1) Analog input in differential input mode

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Full-scale differential input voltage range	V_{ID}	V_{ID} = (PGAxP - PGAxN) (x = 0 to 3)		± 800 /G_{TOTAL}		mV
Input voltage range	V_I	Each of PGAxP and PGAxN pins (x = 0 to 3)	0.2		1.8	V
Common mode input voltage	V_{COM}	$dOFR$ = 0 mV	0.2+(|V_{ID}|x G_{SET1})/2		1.8-(|V_{ID}|x G_{SET1})/2	V
Input bias current	I_{IN}	V_I = 1.0 V			± 50	nA
Input offset current	I_{INOFR}	V_I = 1.0 V			± 20	nA

(2) Analog input in single-ended input mode

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage range	V_I	Each of PGAxP and PGAxN pins (x = 0 to 3) G_{SET1} = 1, G_{SET2} = 1	0.2		1.8	V
Input bias current	I_{IN}	V_I = 1.0 V			± 50	nA

(3) Programmable gain instrumentation amplifier and 24-bit ΔΣ A/D converter

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, $dOFR$ = 0 mV, V_{COM} = 1.0 V, external clock input used, in differential input mode) (1/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES				24	bit
Sampling frequency	f_{S1}	Normal mode		1		MHz
	f_{S2}	Low power mode		0.125		MHz
Output data rate	f_{DATA1}	Normal mode	0.48828		15.625	ksps
	f_{DATA2}	Low power mode	61.03615		1953.125	sps
Gain setting range	G_{TOTAL}	G_{TOTAL} = G_{SET1} × G_{SET2}	1		64	V/V
1st gain setting range	G_{SET1}	In differential input mode only		1, 2, 3, 4, 8		V/V
2nd gain setting range	G_{SET2}	In differential input mode only		1, 2, 4, 8		V/V
Offset adjustment bit range	$dOFFB$			5		bit
Offset adjustment range	$dOFR$	Referred to input	-164/G_{SET1}		+164/G_{SET1}	mV
Offset adjustment steps	$dOFS$	Referred to input		11/G_{SET1}		mV

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(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, d_{OFR} = 0 mV, V_{COM} = 1.0 V, external clock input used, in differential input mode) (2/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Gain error	E_G	T_A = 25°C G_{SET1} = 1, G_{SET2} = 1 Excluding SBIAS error		±0.2	±2.7	%
		T_A = 25°C G_{SET1} = 8, G_{SET2} = 4 Excluding SBIAS error		±0.1		%
Gain drift Note	dE_G	G_{SET1} = 1, G_{SET2} = 1 Excluding SBIAS drift		(5.6)	(22.0)	ppm/°C
		G_{SET1} = 8, G_{SET2} = 4 Excluding SBIAS drift		(9.1)		ppm/°C
Offset error	E_{OS}	T_A = 25°C G_{SET1} = 1, G_{SET2} = 1 Referred to input		±0.32	±2.90	mV
		T_A = 25°C G_{SET1} = 8, G_{SET2} = 4 Referred to input		±0.03		mV
Offset drift Note	dE_{OS}	G_{SET1} = 1, G_{SET2} = 1 Referred to input		(±0.02)	(±6.00)	µV/°C
		G_{SET1} = 8, G_{SET2} = 4 Referred to input		(±0.02)		µV/°C
SND ratio	SNDR	G_{SET1} = 1, G_{SET2} = 1, f_{IN} = 50 Hz Normal mode, pin = -1 dBFS	(82)	(85)		dB
		G_{SET1} = 8, G_{SET2} = 4, f_{IN} = 50 Hz Normal mode, pin = -1 dBFS	(73)	(80)		dB
Noise	Vn	G_{SET1} = 1, G_{SET2} = 1, OSR = 2048		(13)		µVRms
		G_{SET1} = 8, G_{SET2} = 4, OSR = 2048		(0.6)		µVRms
Integral non-linearity error	INL	G_{SET1} = 1, G_{SET2} = 1, OSR = 2048		(±10)		ppmFS
Common mode rejection ratio	CMRR	V_{COM} = 1.0 ± 0.8 V, fin = 50 Hz G_{SET1} = 1, G_{SET2} = 1 Differential input mode	(72)	(90)		dB
Power supply rejection ratio	PSRR	AV_{DD} = 2.7 to 5.5 V G_{SET1} = 1, G_{SET2} = 1 Differential input mode		(85)		dB
ΔΣ A/D converter input clock frequency	f_{ADC}		3.8	4	4.2	MHz

Note Calculate the gain drift and offset drift by using the following expression (for 125°C products):
For gain drift: (MAX(E_G($T_{(-40)}$ to $T_{(125)}$)) - MIN(E_G($T_{(-40)}$ to $T_{(125)}$))) / (125°C -(-40°C))
For offset drift: (MAX(E_{OS}($T_{(-40)}$ to $T_{(125)}$)) - MIN(E_{OS}($T_{(-40)}$ to $T_{(125)}$))) / (125°C -(-40°C))
MAX(E_G($T_{(-40)}$ to $T_{(125)}$)): The maximum value of gain error when the temperature range is -40°C to 125°C
MIN(E_G($T_{(-40)}$ to $T_{(125)}$)): The minimum value of gain error when the temperature range is -40°C to 125°C
MAX(E_{OS}($T_{(-40)}$ to $T_{(125)}$)): The maximum value of offset error when the temperature range is -40°C to 125°C
MIN(E_{OS}($T_{(-40)}$ to $T_{(125)}$)):The minimum value of offset error when the temperature range is -40°C to 125°C

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

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3.6.2 Sensor power supply (SBIAS)

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, C_{OUT} = 0.22 µF, V_{OUT} = 1.0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage range	V_{OUT}		0.5		2.2	V
Output voltage setting steps	V_{STEP}			0.1		V
Output voltage precision	V_A	I_{OUT} = 1 mA	(-3)		(+3)	%
Maximum output current	I_{OUT}		5			mA
Short circuit current	I_{SHORT}	V_{OUT} = 0 V		40	65	mA
Load regulation	L_R	1 mA ≤ I_{OUT} ≤ 5 mA			(15)	mV
Power supply rejection ratio	PSRR	AV_{DD} = 5.0 V + 0.1 $V_{pp\ ripple}$ f = 100 Hz, I_{OUT} = 2.5 mA	(45)	(50)		dB

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

3.6.3 Temperature sensor

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature coefficient for sensor	TC_{SNS}			(756)		µV/°C
Sensor output voltage	V_{TEMP}	T_A = 25°C		226.4		mV

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

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3.6.4 A/D converter characteristics

(1) When positive reference voltage (+) = AV_{DD} (ADREFP1 = 0, ADREFP0 = 0), negative reference voltage (-) = AV_{SS} (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = AV_{DD}, negative reference voltage (-) = AV_{SS})

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error Note 1	AINL	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V		1.2	±6.5	LSB
			2.7 V ≤ AV_{DD} ≤ 5.5 V		1.2	±7.0	LSB
Conversion time	t_{CONV}	10-bit resolution	4.0 V ≤ AV_{DD} ≤ 5.5 V	2.125		39	µs
			2.7 V ≤ AV_{DD} ≤ 5.5 V	3.1875		39	µs
Zero-scale error Notes 1, 2	E_{ZS}	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±0.50	%FSR
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Full-scale error Notes 1, 2	E_{FS}	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±0.50	%FSR
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Integral linearity error Note 1	ILE	10-bit resolution ANI0 to ANI9, SBIAS	4.0 V ≤ AV_{DD} ≤ 5.5 V			±3.5	LSB
			2.7 V ≤ AV_{DD} ≤ 5.5 V			±4.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±2.0	LSB
Analog input voltage	V_{AIN}	ANI0 to ANI9		AV_{SS}		AV_{DD}	V

Note 1. Excludes quantization error (±1/2 LSB).
Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Caution The number of pins depends on the product. For details, see a list of pin functions.

(2) When positive reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), negative reference voltage (-) = AV_{SS} (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = V_{BGR}, negative reference voltage (-) = AV_{SS})

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	t_{CONV}	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V	17		39	µs
Zero-scale error Notes 1, 2	E_{ZS}	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±0.60	%FSR
Integral linearity error Note 1	ILE	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±2.0	LSB
Differential linearity error Note 1	DLE	8-bit resolution	2.7 V ≤ AV_{DD} ≤ 5.5 V			±1.0	LSB
Internal reference voltage (+)	V_{BGR}	2.7 V ≤ AV_{DD} ≤ 5.5 V		V_{BGR} Note 3			V
Analog input voltage	V_{AIN}	ANI0 to ANI9		0		V_{BGR}	V

Note 1. Excludes quantization error (±1/2 LSB).
Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.
Note 3. See the Internal reference voltage characteristics.

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3.6.5 12-bit D/A converter

(1) When positive reference voltage (+) = AV_{DD} (DACVRF = 0)

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = AV_{DD})

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	DARES				(12)	bit
Output voltage range	DAOUT	12-bit resolution	0.35		AV_{DD}-0.47	V
Integral non-linearity error	DAILE	12-bit resolution			±4.0	LSB
Differential non-linearity error	DADLE	12-bit resolution			±1.0	LSB
Offset error	DAErr	12-bit resolution			±30	mV
Gain error	DAEG	12-bit resolution			±20	mV
Settling time	DAtset	12-bit resolution, C_L = 50 pF, R_L = 10 kΩ			(60)	μs

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

(2) When positive reference voltage (+) = internal reference voltage (DACVRF = 1)

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, positive reference voltage (+) = VREFDA)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	DARES				(8)	bit
Internal reference voltage	VREFDA	8-bit resolution	1.34	1.45	1.54	V
Output voltage range	DAOUT	8-bit resolution	0.35		VREFDA	V
Integral non-linearity error	DAILE	8-bit resolution			±1.0	LSB
Differential non-linearity error	DADLE	8-bit resolution			±1.0	LSB
Offset error	DAErr	8-bit resolution			±30	mV
Gain error	DAEG	8-bit resolution			±20	mV
Settling time	DAtset	8-bit resolution, C_L = 50 pF, R_L = 10 kΩ			(60)	μs

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.
Remark 3. Offset error and gain error do not include error in the internal reference voltage.

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3.6.6 Configurable amplifier

(T_A = -40 to +125°C, 2.7 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V, V_{COM} = 1/2 AV_{DD}, internally connected voltage follower)

AMP0 configuration SW setting: Positive (+) pin = ANX1, negative (-) pin = ANX0

AMP1 configuration SW setting: Positive (+) pin = ANX3, negative (-) pin = ANX2

AMP2 configuration SW setting: Positive (+) pin = ANX5, negative (-) pin = ANX4

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage	V_{IN}		AV_{SS}		AV_{DD}	V
Output voltage	V_{OL}	I_L= -1 mA, AV_{DD} = 2.7 to 5.5 V		AV_{SS} +0.02	AV_{SS} +0.07	V
	V_{OH}	I_L= 1 mA, AV_{DD} = 2.7 to 5.5 V	AV_{DD} -0.15	AV_{DD} -0.02		V
Maximum output current	I_{OUT}	4.5 V ≤ AV_{DD} ≤ 5.5 V	±10			mA
		2.7 V ≤ AV_{DD} ≤ 5.5 V	±5			mA
Input-referred offset voltage	V_{OFF}	T_A = 25°C without trimming I_L = 0 mA, V_{COM} = 1.0 V		±1	±4	mV
		T_A = 25°C with trimming I_L = 0 mA, V_{COM} = 1.0 V			±0.35	mV
Temperature coefficient for inputreferred offset voltage	V_{OTC}	I_L = 0 mA		(±2)	(±8)	μV/°C
Slew rate	SR1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(0.1)		V/μs
	SR2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(0.8)		V/μs
Gain bandwidth	GBW1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(350)		kHz
	GBW2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(1.8)		MHz
Phase margin	θM1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(70)		deg
	θM2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(60)		deg
Settling time	tset1	Normal mode C_L = 50 pF, R_L = 10 kΩ		(20)		μs
	tset2	High-speed mode C_L = 50 pF, R_L = 10 kΩ		(10)		μs
Peak-to-peak voltage noise	Enb	0.1 to 10 Hz Normal mode C_L = 50 pF, R_L = 10 kΩ		(2.0)		μVrms
Input-referred noise	En	f = 1 kHz Normal mode C_L = 50 pF, R_L = 10 kΩ		(70)		nV/√Hz
Common mode rejection ratio	CMRR	f = 1 KHz, C_L = 50 pF, R_L = 10 kΩ		(70)		dB
Power supply rejection ratio	PSRR	2.7 V ≤ AV_{DD} ≤ 5.5 V C_L = 50 pF, R_L = 10 kΩ		(62)		dB

(Remarks are listed on the next page.)

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Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.
Remark 2. The TYP. conditions are the conditions when TA = 25°C and AVDD = 5.0 V.
Remark 3. Unless otherwise specified, offset trimming has proceeded.
Remark 4. Unless otherwise specified, values are for operation in normal mode.

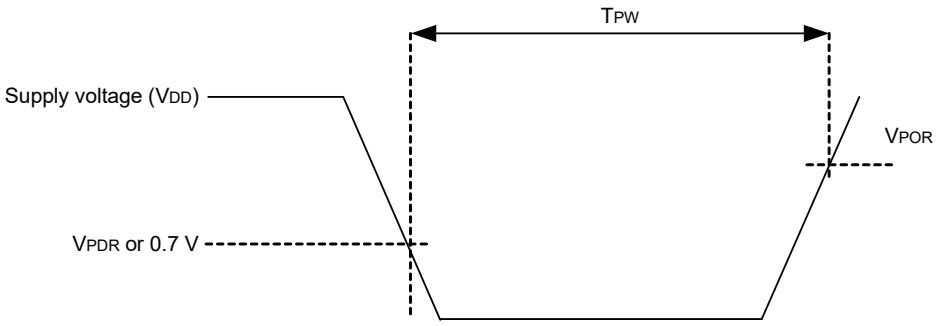
3.6.7 POR characteristics

(TA = -40 to +125°C, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	VPOR	Voltage threshold on VDD rising	1.48	1.56	1.62	V
	VPDR	Voltage threshold on VDD falling Note 1	1.47	1.55	1.61	V
Minimum pulse width Note 2	TPW		300			µs

Note 1. However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 3.4 AC Characteristics.

Note 2. Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



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3.6.8 LVD characteristics

(1) LVD detection voltage in reset mode and interrupt mode

(T_A = -40 to +125°C, $V_{PDR} \le AV_{DD} = V_{DD} \le$ 5.5 V, $AV_{SS} = V_{SS}$ = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Voltage detection threshold	Supply voltage level	V_{LVD0}	Rising edge	4.62	4.74	4.94	V
			Falling edge	4.52	4.64	4.84	V
		V_{LVD1}	Rising edge	4.50	4.62	4.82	V
			Falling edge	4.40	4.52	4.71	V
		V_{LVD2}	Rising edge	4.30	4.42	4.61	V
			Falling edge	4.21	4.32	4.51	V
		V_{LVD3}	Rising edge	3.13	3.22	3.39	V
			Falling edge	3.07	3.15	3.31	V
		V_{LVD4}	Rising edge	2.95	3.02	3.17	V
			Falling edge	2.89	2.96	3.09	V
		V_{LVD5}	Rising edge	2.74	2.81	2.95	V
			Falling edge	2.68	2.75	2.88	V
		V_{LVD6}	Rising edge	2.55	2.61	2.74	V
			Falling edge	2.49	2.55	2.67	V
Minimum pulse width		t_{LW}		300			µs
Detection delay time						300	µs

(2) LVD detection voltage in interrupt & reset mode

(T_A = -40 to +125°C, $V_{PDR} \le AV_{DD} = V_{DD} \le$ 5.5 V, $AV_{SS} = V_{SS}$ = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Voltage detection threshold	V_{LVDD6}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 0, 0, falling reset voltage		2.49	2.55	2.67	V
	V_{LVDD4}	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.95	3.02	3.17	V
			Falling interrupt voltage	2.89	2.96	3.09	V
	V_{LVDD3}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.13	3.22	3.39	V
			Falling interrupt voltage	3.07	3.15	3.31	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 0, 1, falling reset voltage		2.68	2.75	2.88	V
	V_{LVDD2}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.30	4.42	4.61	V
			Falling interrupt voltage	4.21	4.32	4.51	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 1, 0, falling reset voltage		2.68	2.75	2.88	V
	V_{LVDD1}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.50	4.62	4.82	V
			Falling interrupt voltage	4.40	4.52	4.71	V
	V_{LVDD5}	V_{POC2}, V_{POC1}, V_{POC0} = 0, 1, 1, falling reset voltage		2.68	2.75	2.88	V
	V_{LVDD3}	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	3.13	3.22	3.39	V
			Falling interrupt voltage	3.07	3.15	3.31	V
	V_{LVDD0}	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	4.62	4.74	4.94	V
			Falling interrupt voltage	4.52	4.64	4.84	V

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3.6.9 Power supply voltage rising slope characteristics

(TA = -40 to +125°C, VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	SVDD				50	V/ms

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 3.4 AC Characteristics.

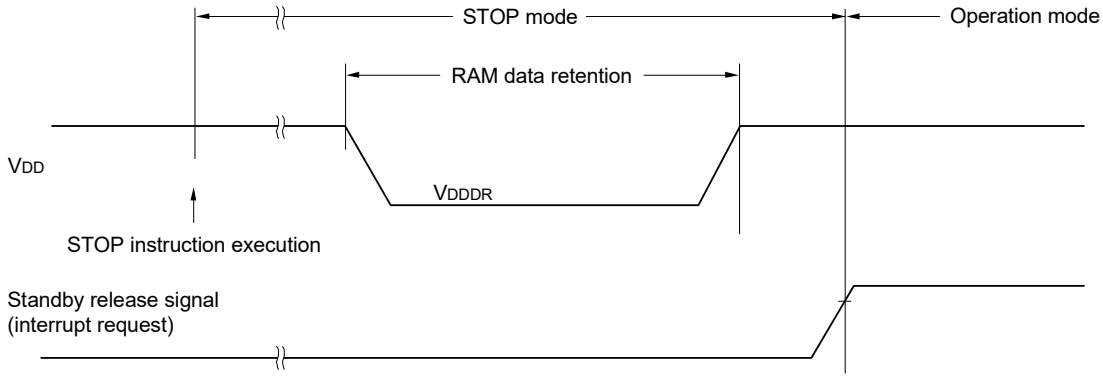
3.7 RAM Data Retention Characteristics

(TA = -40 to +125°C, VSS = 0 V))

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.47 Notes 1, 2		5.5	V

Note 1. The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.

Note 2. Enter STOP mode before the supply voltage falls below the recommended operating voltage.



3.8 Flash Memory Programming Characteristics

(TA = -40 to +125°C Note 4, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	fCLK	2.4 V ≤ VDD ≤ 5.5 V	1		24	MHz
Number of code flash rewrites Notes 1, 2, 3	Cerwr	Retained for 20 years TA = 85°C Note 5	1,000			Times
Number of data flash rewrites Notes 1, 2, 3		Retained for 1 year TA = 25°C Note 5		1,000,000		
		Retained for 5 years TA = 85°C Note 5	100,000			
		Retained for 20 years TA = 85°C Note 5	10,000			

Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

Note 2. When using flash memory programmer and Renesas Electronics self-programming library

Note 3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

Note 4. The range is from TA = -40 to +105°C when if the flash memory programmer is in use.

Note 5. This temperature is the average value at which data are retained.

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3.9 Dedicated Flash Memory Programmer Communication (UART)

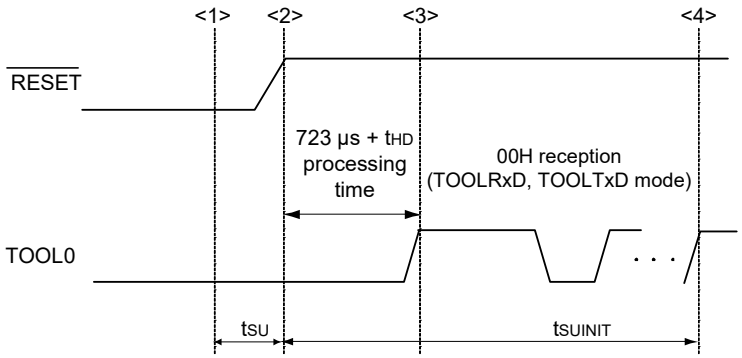
(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

3.10 Timing for Switching Flash Memory Programming Modes

(T_A = -40 to +105°C, 2.4 V ≤ AV_{DD} = V_{DD} ≤ 5.5 V, AV_{SS} = V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	t_{SUINIT}	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	t_{SU}	POR and LVD reset must end before the external reset ends.	10			µs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	t_{HD}	POR and LVD reset must end before the external reset ends.	1			ms



<1> The low level is input to the TOOL0 pin.
<2> The external reset ends (POR and LVD reset must end before the external reset ends).
<3> The TOOL0 pin is set to the high level.
<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark t_{SUINIT}: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.
t_{SU}: How long from when the TOOL0 pin is placed at the low level until a pin reset ends
t_{HD}: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

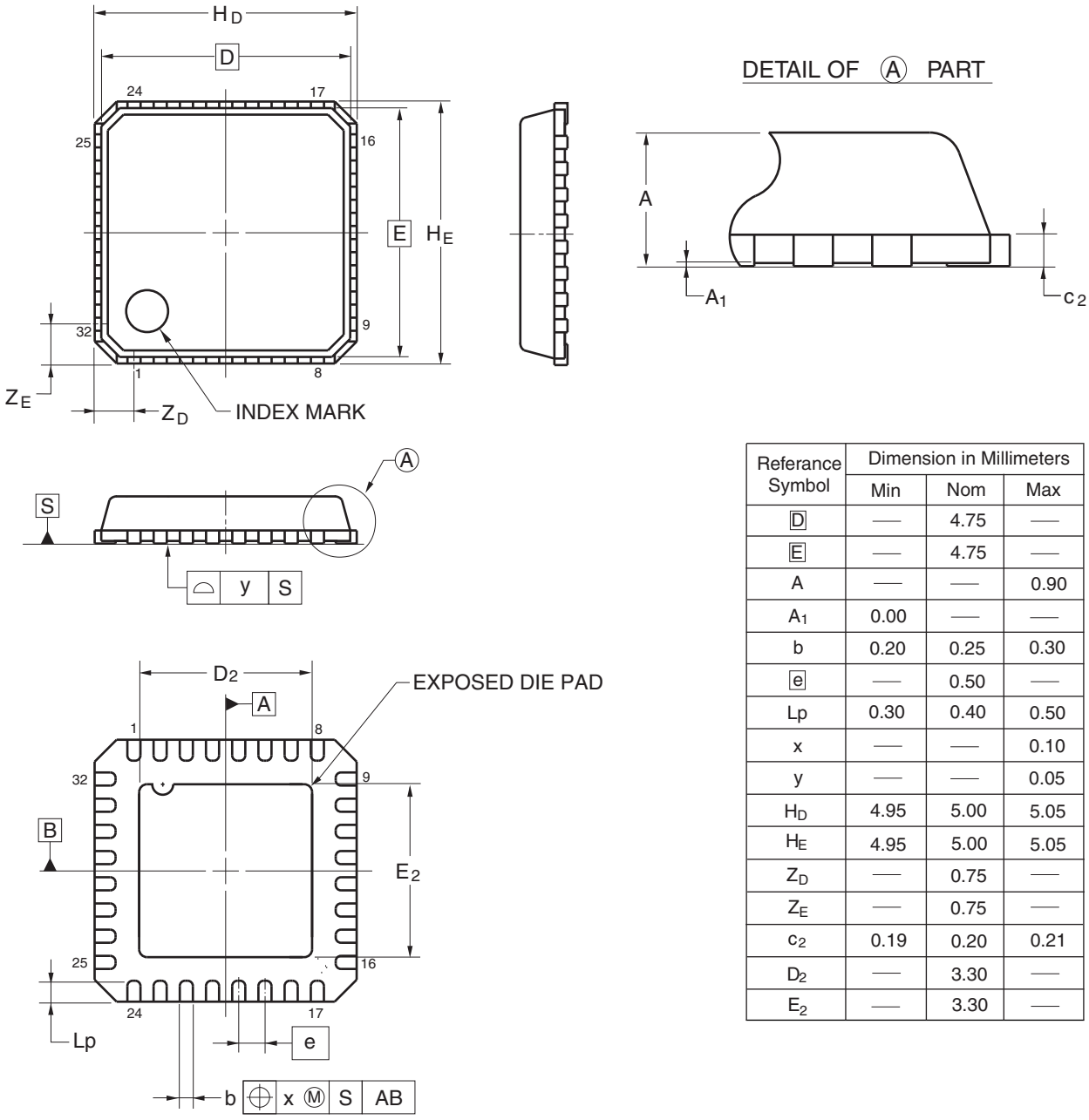
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4. PACKAGE DRAWINGS

4.1 32-pin products

R5F11CBCGNA, R5F11CBCMNA

JEITA Package code	RENESAS code	Previous code	MASS(TYP.)[g]
P-HVQFN32-5x5-0.50	PVQN0032KE-A	P32K9-50B-BAH	0.058



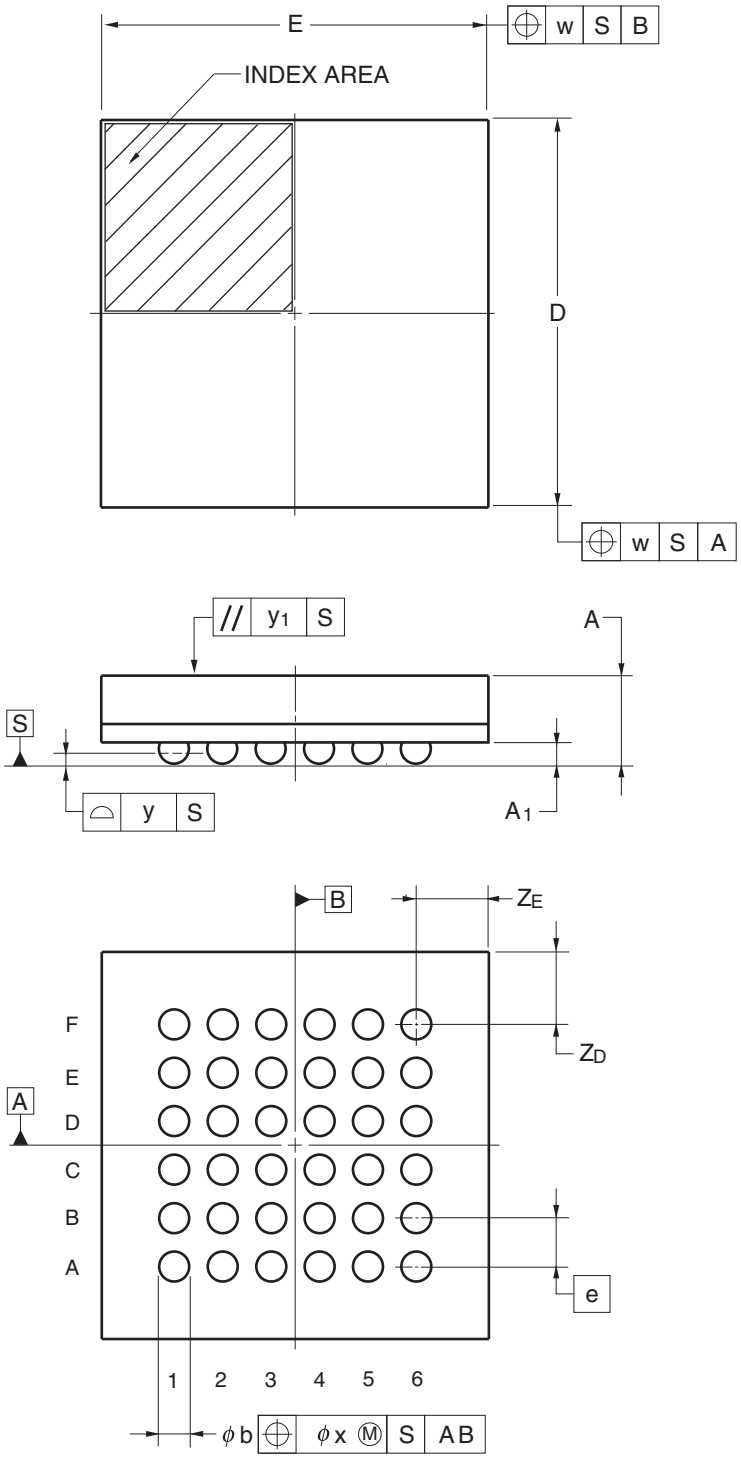
Referance Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	4.75	—
E	—	4.75	—
A	—	—	0.90
A_1	0.00	—	—
b	0.20	0.25	0.30
e	—	0.50	—
Lp	0.30	0.40	0.50
x	—	—	0.10
y	—	—	0.05
H_D	4.95	5.00	5.05
H_E	4.95	5.00	5.05
Z_D	—	0.75	—
Z_E	—	0.75	—
c_2	0.19	0.20	0.21
D_2	—	3.30	—
E_2	—	3.30	—

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4.2 36-pin products

R5F11CCCGBG, R5F11CCCMBG

JEITA Package code	RENESAS code	Previous code	MASS(TYP.)[g]
P-TFBGA36-4x4-0.50	PTBG0036KA-A	P36F1-50-AA6	0.027



Referance Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	3.90	4.00	4.10
E	3.90	4.00	4.10
A	—	—	1.10
A_1	0.17	0.22	0.27
e	—	0.50	—
b	0.26	0.31	0.36
x	—	—	0.05
y	—	—	0.08
y_1	—	—	0.20
Z_D	—	0.75	—
Z_E	—	0.75	—
w	—	—	0.20

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REVISION HISTORY	RL78/I1E Datasheet

Rev.	Date	Description	
		Page	Summary
1.30	Mar 29, 2024	p.3	Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E
			Modification of Ordering Part Number in 1.2 Ordering Information
1.20	May 31, 2023	All	The module name for CSI was changed to simplified SPI.
		p.2	Addition of Note in 1.1 Features
		p.3	Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E
			Addition of R5F11CBCGNA#00 in Fields of Application Notes G
1.10	Jun 30, 2016	4	Addition of products name in 1.3.1 32-pin products
		5	Addition of products name in 1.3.2 36-pin products
		10	Change of DTC in 1.6 Outline of Functions
		10	Addition of Note1 in 1.6 Outline of Functions
		43	Change of 2.5.1 (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock in input)
		57	Change of 2.7 RAM Data Retention Characteristics
		57	Change of 2.8 Flash Memory Programming Characteristics
		62	Change of 3.2.2 On-chip oscillator characteristics
		91	Change of 3.5.1 (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock in input)
		105	Change of 3.7 RAM Data Retention Characteristics
		105	Change of 3.8 Flash Memory Programming Characteristics
1.00	Jul 31, 2015	—	First Edition issued

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General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)
   A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.
2. Processing at power-on
   The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.
3. Input of signal during power-off state
   Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.
4. Handling of unused pins
   Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.
5. Clock signals
   After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.
6. Voltage application waveform at input pin
   Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).
7. Prohibition of access to reserved addresses
   Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.
8. Differences between products
   Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

Contact Information

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